

Rail-to-Rail Input/Output, 10 MHz Op Amps

Features

- Rail-to-Rail Input/Output
- Wide Bandwidth: 10 MHz (typical)
- Low Noise: 8.7 nV/ $\sqrt{\text{Hz}}$ at 10 kHz (typical)
- Low Offset Voltage:
 - Industrial Temperature: $\pm 500 \mu\text{V}$ (max.)
 - Extended Temperature: $\pm 250 \mu\text{V}$ (max.)
- Mid-Supply V_{REF} : MCP6021 and MCP6023
- Low Supply Current: 1 mA (typical)
- Total Harmonic Distortion:
 - 0.00053% (typical, $G = 1 \text{ V/V}$)
- Unity Gain Stable
- Power Supply Range: 2.5V to 5.5V
- Temperature Range:
 - Industrial: -40°C to +85°C
 - Extended: -40°C to +125°C

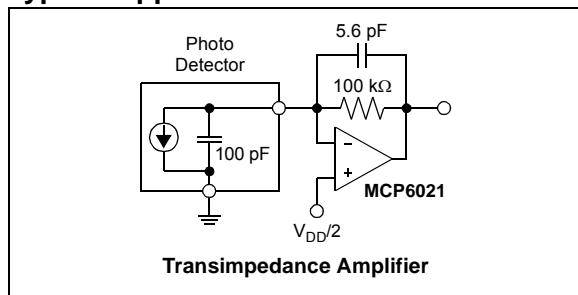
Applications

- Automotive
- Multi-Pole Active Filters
- Audio Processing
- DAC Buffer
- Test Equipment
- Medical Instrumentation

Design Aids

- SPICE Macro Models
- FilterLab® Software
- MPLAB® Mindi™ Analog Simulator
- Microchip Advanced Part Selector (MAPS)
- Analog Demonstration and Evaluation Boards
- Application Notes

Typical Application



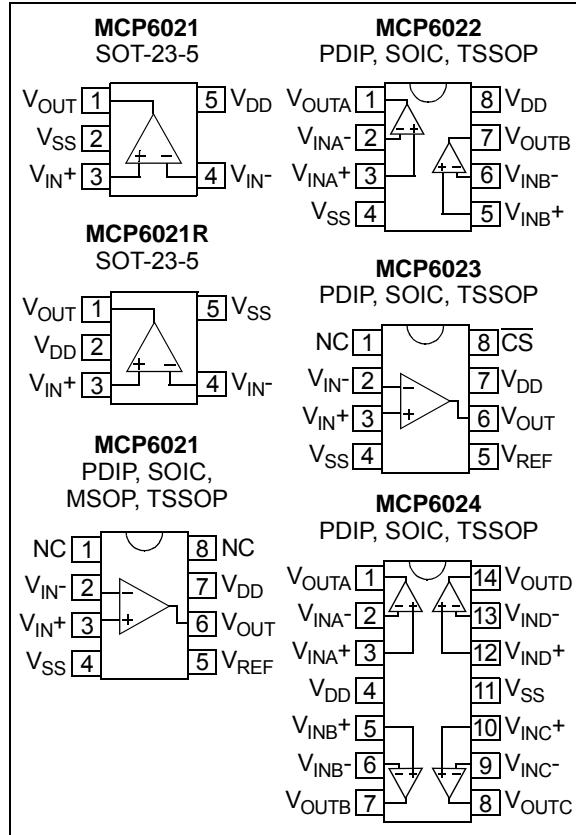
Description

The MCP6021, MCP6021R, MCP6022, MCP6023 and MCP6024 from Microchip Technology Inc. are rail-to-rail input and output operational amplifiers with high performance. Key specifications include: wide bandwidth (10 MHz), low noise (8.7 nV/ $\sqrt{\text{Hz}}$), low input offset voltage and low distortion (0.00053% THD+N). The MCP6023 also offers a Chip Select pin (\overline{CS}) that gives power savings when the part is not in use.

The single MCP6021 and MCP6021R are available in SOT-23-5 packages. The single MCP6021, single MCP6023 and dual MCP6022 are available in 8-lead PDIP, SOIC and TSSOP packages. The Extended Temperature single MCP6021 is available in 8-lead MSOP. The quad MCP6024 is offered in 14-lead PDIP, SOIC and TSSOP packages.

The MCP6021/1R/2/3/4 family is available in Industrial and Extended temperature ranges. It has a power supply range of 2.5V to 5.5V.

Package Types



MCP6021/1R/2/3/4

NOTES:

1.0 ELECTRICAL CHARACTERISTICS

Absolute Maximum Ratings†

$V_{DD} - V_{SS}$	7.0V
Current Analog Input Pins (V_{IN^+} , V_{IN^-})	± 2 mA
Analog Inputs (V_{IN^+} , V_{IN^-}) ‡	$V_{SS} - 1.0V$ to $V_{DD} + 1.0V$
All Other Inputs and Outputs	$V_{SS} - 0.3V$ to $V_{DD} + 0.3V$
Difference Input Voltage	$ V_{DD} - V_{SS} $
Output Short-Circuit Current	Continuous
Current at Output and Supply Pins	± 30 mA
Storage Temperature	-65°C to +150°C
Maximum Junction Temperature	+150°C
ESD Protection on All Pins (HBM; MM)	≥ 2 kV; 200V

† **Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational listings of this specification is not implied. Exposure to maximum rating conditions for extended periods may affect device reliability.

‡ See [Section 4.1.2, Input Voltage Limits](#).

DC ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $T_A = +25^\circ C$, $V_{DD} = +2.5V$ to $+5.5V$, $V_{SS} = GND$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$ and $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Input Offset						
Input Offset Voltage:						
Industrial Temperature Parts	V_{OS}	-500	—	+500	µV	$V_{CM} = 0V$
	V_{OS}	-250	—	+250	µV	$V_{CM} = 0V$, $V_{DD} = 5.0V$
	V_{OS}	-2.5	—	+2.5	mV	$V_{CM} = 0V$, $V_{DD} = 5.0V$, $T_A = -40^\circ C$ to $+125^\circ C$
Input Offset Voltage Temperature Drift	$\Delta V_{OS}/\Delta T_A$	—	± 3.5	—	µV/°C	$T_A = -40^\circ C$ to $+125^\circ C$
Power Supply Rejection Ratio	PSRR	74	90	—	dB	$V_{CM} = 0V$
Input Current and Impedance						
Input Bias Current:	I_B	—	1	—	pA	
	I_B	—	30	150	pA	$T_A = +85^\circ C$
	I_B	—	640	5,000	pA	$T_A = +125^\circ C$
Input Offset Current	I_{OS}	—	± 1	—	pA	
Common-Mode Input Impedance	Z_{CM}	—	$10^{13} 6$	—	ΩpF	
Differential Input Impedance	Z_{DIFF}	—	$10^{13} 3$	—	ΩpF	
Common-Mode						
Common-Mode Input Range	V_{CMR}	$V_{SS} - 0.3$	—	$V_{DD} + 0.3$	V	
Common-Mode Rejection Ratio	CMRR	74	90	—	dB	$V_{DD} = 5V$, $V_{CM} = -0.3V$ to $5.3V$
	CMRR	70	85	—	dB	$V_{DD} = 5V$, $V_{CM} = 3.0V$ to $5.3V$
	CMRR	74	90	—	dB	$V_{DD} = 5V$, $V_{CM} = -0.3V$ to $3.0V$
Voltage Reference (MCP6021 and MCP6023 only)						
V_{REF} Accuracy ($V_{REF} - V_{DD}/2$)	V_{REF_ACC}	-50	—	+50	mV	
V_{REF} Temperature Drift	$\Delta V_{REF}/\Delta T_A$	—	± 100	—	µV/°C	$T_A = -40^\circ C$ to $+125^\circ C$
Open-Loop Gain						
DC Open-Loop Gain (Large Signal)	A_{OL}	90	110	—	dB	$V_{CM} = 0V$, $V_{OUT} = V_{SS} + 0.3V$ to $V_{DD} - 0.3V$
Output						
Maximum Output Voltage Swing	V_{OL} , V_{OH}	$V_{SS} + 15$	—	$V_{DD} - 20$	mV	0.5V input overdrive
Output Short Circuit Current	I_{SC}	—	± 30	—	mA	$V_{DD} = 2.5V$
	I_{SC}	—	± 22	—	mA	$V_{DD} = 5.5V$
Power Supply						
Supply Voltage	V_{DD}	2.5	—	5.5	V	
Quiescent Current per Amplifier	I_Q	0.5	1.0	1.35	mA	$I_O = 0$

MCP6021/1R/2/3/4

AC ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
AC Response						
Gain Bandwidth Product	GBWP	—	10	—	MHz	
Phase Margin	PM	—	65	—	°	$G = +1 \text{ V/V}$
Settling Time, 0.2%	t_{SETTLE}	—	250	—	ns	$G = +1 \text{ V/V}$, $V_{OUT} = 100 \text{ mV}_{\text{p-p}}$
Slew Rate	SR	—	7.0	—	$\text{V}/\mu\text{s}$	
Total Harmonic Distortion Plus Noise						
$f = 1 \text{ kHz}$, $G = +1 \text{ V/V}$	THD + N	—	0.00053	—	%	$V_{OUT} = 0.25\text{V}$ to 3.25V ($1.75\text{V} \pm 1.50\text{V}_{\text{PK}}$), $V_{DD} = 5.0\text{V}$, $BW = 22 \text{ kHz}$
$f = 1 \text{ kHz}$, $G = +1 \text{ V/V}$, $R_L = 600\Omega$	THD + N	—	0.00064	—	%	$V_{OUT} = 0.25\text{V}$ to 3.25V ($1.75\text{V} \pm 1.50\text{V}_{\text{PK}}$), $V_{DD} = 5.0\text{V}$, $BW = 22 \text{ kHz}$
$f = 1 \text{ kHz}$, $G = +1 \text{ V/V}$	THD + N	—	0.0014	—	%	$V_{OUT} = 4\text{V}_{\text{P-P}}$, $V_{DD} = 5.0\text{V}$, $BW = 22 \text{ kHz}$
$f = 1 \text{ kHz}$, $G = +10 \text{ V/V}$	THD + N	—	0.0009	—	%	$V_{OUT} = 4\text{V}_{\text{P-P}}$, $V_{DD} = 5.0\text{V}$, $BW = 22 \text{ kHz}$
$f = 1 \text{ kHz}$, $G = +100 \text{ V/V}$	THD + N	—	0.005	—	%	$V_{OUT} = 4\text{V}_{\text{P-P}}$, $V_{DD} = 5.0\text{V}$, $BW = 22 \text{ kHz}$
Noise						
Input Noise Voltage	E_{ni}	—	2.9	—	$\mu\text{V}_{\text{p-p}}$	$f = 0.1 \text{ Hz}$ to 10 Hz
Input Noise Voltage Density	e_{ni}	—	8.7	—	$\text{nV}/\sqrt{\text{Hz}}$	$f = 10 \text{ kHz}$
Input Noise Current Density	i_{ni}	—	3	—	$\text{fA}/\sqrt{\text{Hz}}$	$f = 1 \text{ kHz}$

MCP6023 CHIP SELECT (CS) ELECTRICAL CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
CS Low Specifications						
CS Logic Threshold, Low	V_{IL}	V_{SS}	—	0.2 V_{DD}	V	
CS Input Current, Low	I_{CSL}	-1.0	0.01	—	μA	$\overline{CS} = V_{SS}$
CS High Specifications						
CS Logic Threshold, High	V_{IH}	0.8 V_{DD}	—	V_{DD}	V	
CS Input Current, High	I_{CSH}	—	0.01	2.0	μA	$\overline{CS} = V_{DD}$
GND Current	I_{SS}	-2	-0.05	—	μA	$\overline{CS} = V_{DD}$
Amplifier Output Leakage	$I_{O(\text{LEAK})}$	—	0.01	—	μA	$\overline{CS} = V_{DD}$
CS Dynamic Specifications						
CS Low to Amplifier Output Turn-on Time	t_{ON}	—	2	10	μs	$G = +1$, $V_{IN} = V_{SS}$, $\overline{CS} = 0.2 \text{ V}_{DD}$ to $V_{OUT} = 0.45 \text{ V}_{DD}$ time
CS High to Amplifier Output High-Z Time	t_{OFF}	—	0.01	—	μs	$G = +1$, $V_{IN} = V_{SS}$, $\overline{CS} = 0.8 \text{ V}_{DD}$ to $V_{OUT} = 0.05 \text{ V}_{DD}$ time
Hysteresis	V_{HYST}	—	0.6	—	V	$V_{DD} = 5.0\text{V}$, internal switch

TEMPERATURE CHARACTERISTICS

Electrical Specifications: Unless otherwise indicated, $V_{DD} = +2.5V$ to $+5.5V$ and $V_{SS} = GND$.

Parameters	Sym.	Min.	Typ.	Max.	Units	Conditions
Temperature Ranges						
Industrial Temperature Range	T_A	-40	—	+85	°C	
Extended Temperature Range	T_A	-40	—	+125	°C	
Operating Temperature Range	T_A	-40	—	+125	°C	(Note 1)
Storage Temperature Range	T_A	-65	—	+150	°C	
Thermal Package Resistances						
Thermal Resistance, 5L-SOT-23	θ_{JA}	—	256	—	°C/W	
Thermal Resistance, 8L-PDIP	θ_{JA}	—	85	—	°C/W	
Thermal Resistance, 8L-SOIC	θ_{JA}	—	163	—	°C/W	
Thermal Resistance, 8L-MSOP	θ_{JA}	—	206	—	°C/W	
Thermal Resistance, 8L-TSSOP	θ_{JA}	—	124	—	°C/W	
Thermal Resistance, 14L-PDIP	θ_{JA}	—	70	—	°C/W	
Thermal Resistance, 14L-SOIC	θ_{JA}	—	120	—	°C/W	
Thermal Resistance, 14L-TSSOP	θ_{JA}	—	100	—	°C/W	

Note 1: The industrial temperature devices operate over this Extended temperature range, but with reduced performance. In any case, the internal Junction Temperature (T_J) must not exceed the absolute maximum specification of $+150^{\circ}C$.

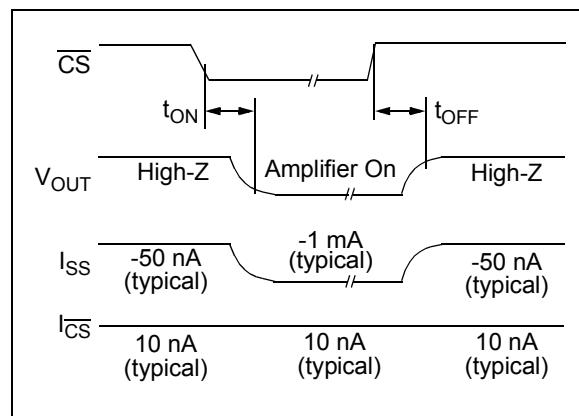


FIGURE 1-1: Timing Diagram for the \overline{CS} Pin on the MCP6023.

1.1 Test Circuits

The test circuits used for the DC and AC tests are shown in Figure 1-2 and Figure 1-3. The bypass capacitors are laid out according to the rules discussed in Section 4.7 “Supply Bypass”.

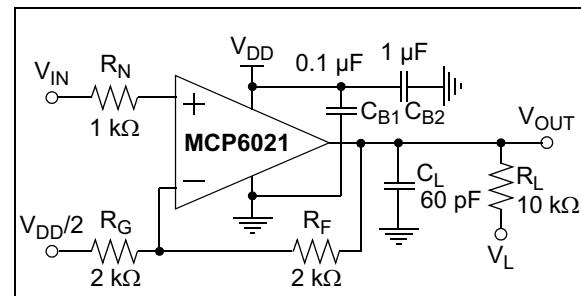


FIGURE 1-2: AC and DC Test Circuit for Most Non-Inverting Gain Conditions.

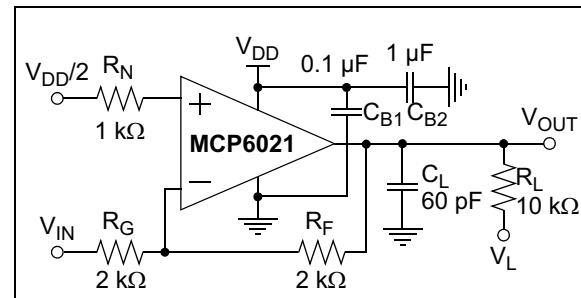


FIGURE 1-3: AC and DC Test Circuit for Most Inverting Gain Conditions.

MCP6021/1R/2/3/4

NOTES:

2.0 TYPICAL PERFORMANCE CURVES

Note: The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10\text{k}\Omega$ to $V_{DD}/2$ and $C_L = 60\text{ pF}$.

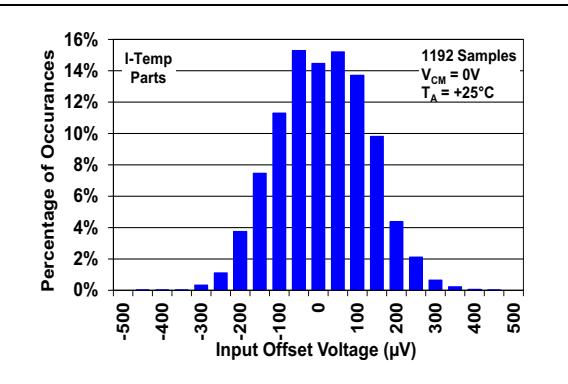


FIGURE 2-1: Input Offset Voltage (Industrial Temperature Parts).

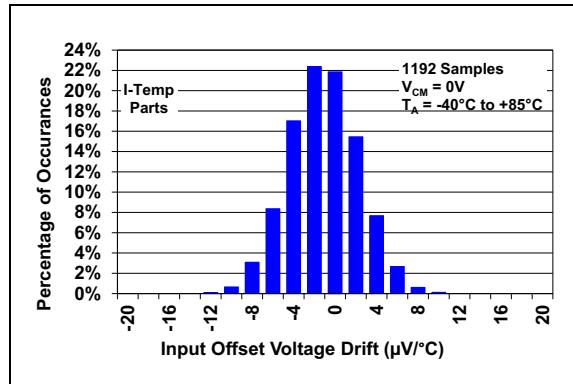


FIGURE 2-4: Input Offset Voltage Drift (Industrial Temperature Parts).

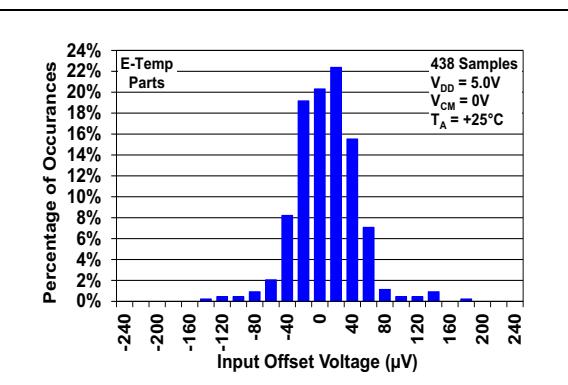


FIGURE 2-2: Input Offset Voltage (Extended Temperature Parts).

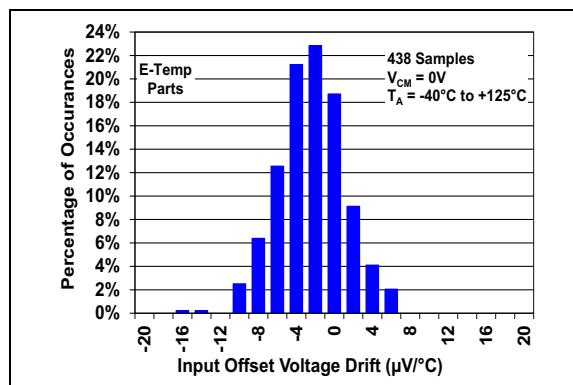


FIGURE 2-5: Input Offset Voltage Drift (Extended Temperature Parts).

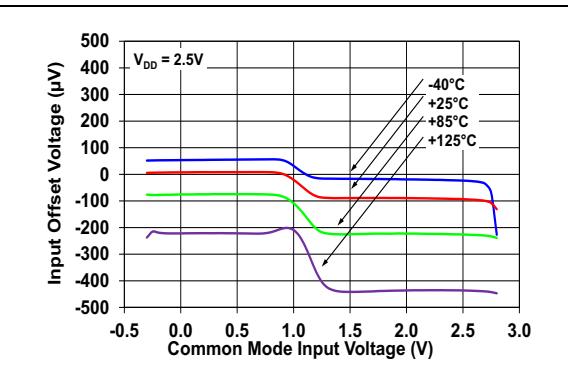


FIGURE 2-3: Input Offset Voltage vs. Common-Mode Input Voltage with $V_{DD} = 2.5\text{V}$.

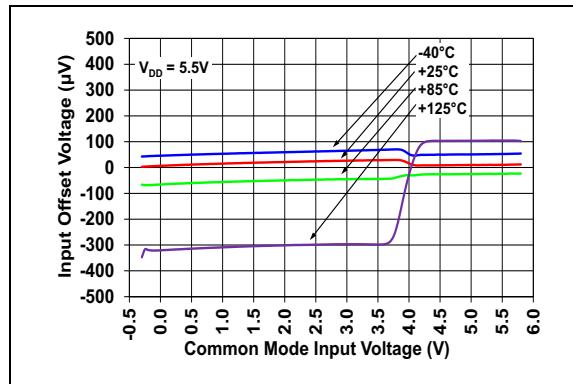


FIGURE 2-6: Input Offset Voltage vs. Common-Mode Input Voltage with $V_{DD} = 5.5\text{V}$.

MCP6021/1R/2/3/4

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

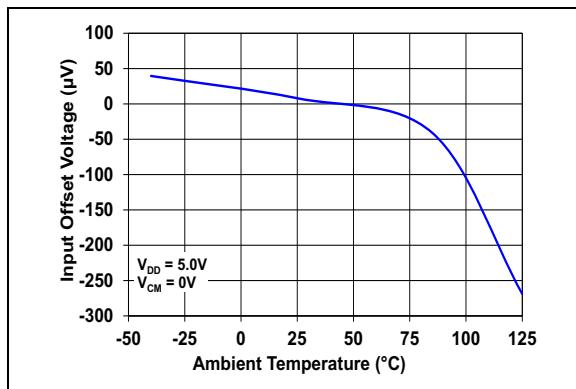


FIGURE 2-7: Input Offset Voltage vs. Temperature.

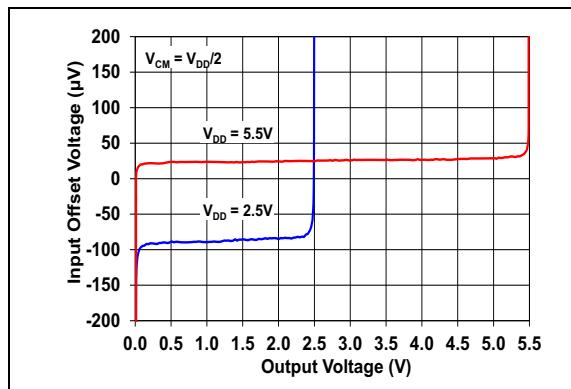


FIGURE 2-10: Input Offset Voltage vs. Output Voltage.

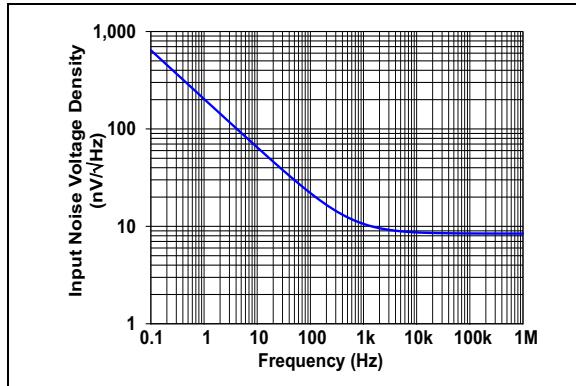


FIGURE 2-8: Input Noise Voltage Density vs. Frequency.

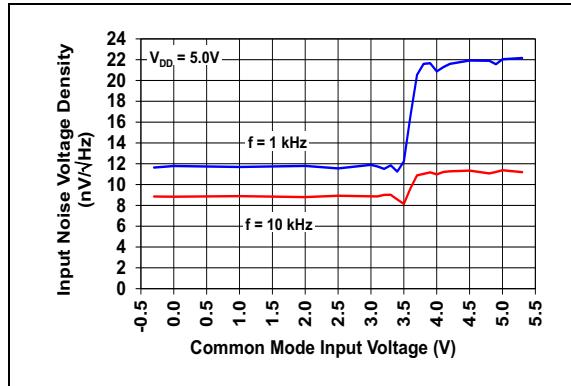


FIGURE 2-11: Input Noise Voltage Density vs. Common-Mode Input Voltage.

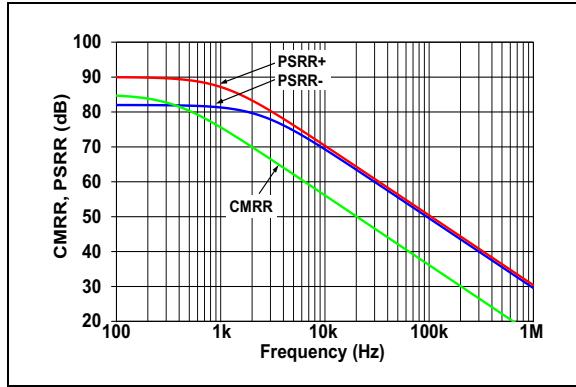


FIGURE 2-9: CMRR, PSRR vs. Frequency.

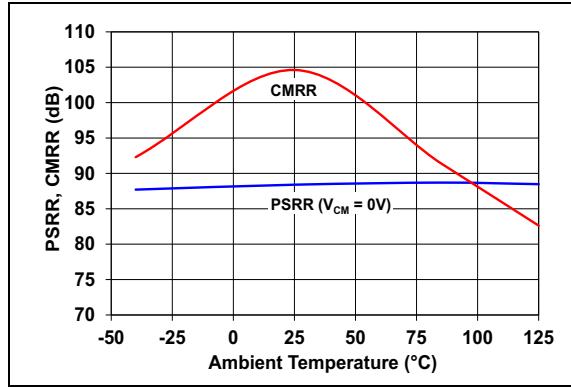


FIGURE 2-12: CMRR, PSRR vs. Temperature.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10\text{k}\Omega$ to $V_{DD}/2$ and $C_L = 60\text{pF}$.

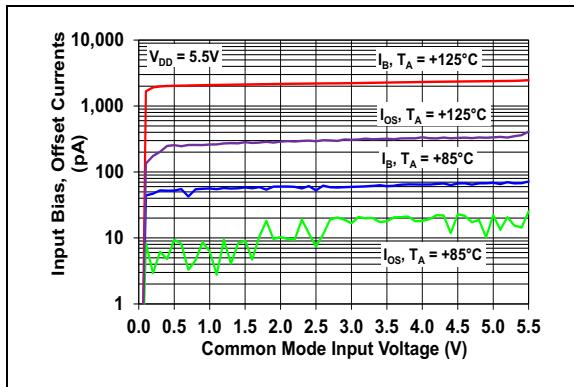


FIGURE 2-13: Input Bias, Offset Currents vs. Common-Mode Input Voltage.

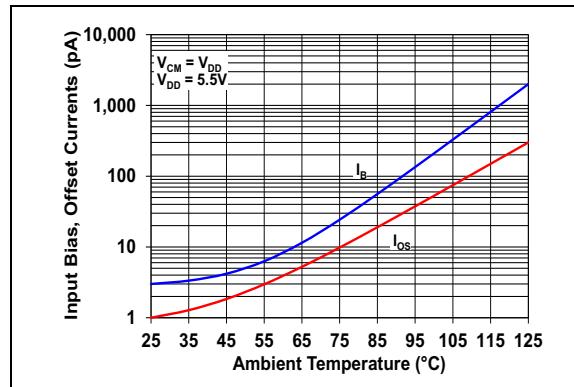


FIGURE 2-16: Input Bias, Offset Currents vs. Temperature.

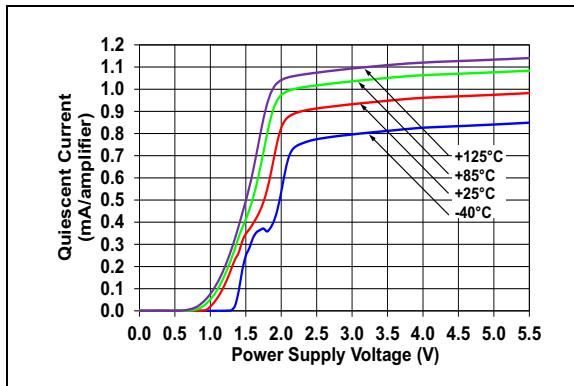


FIGURE 2-14: Quiescent Current vs. Supply Voltage.

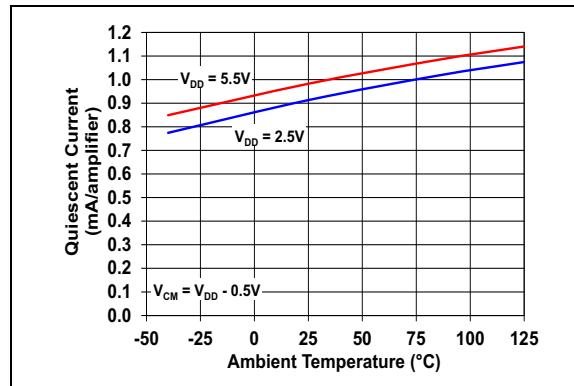


FIGURE 2-17: Quiescent Current vs. Temperature.

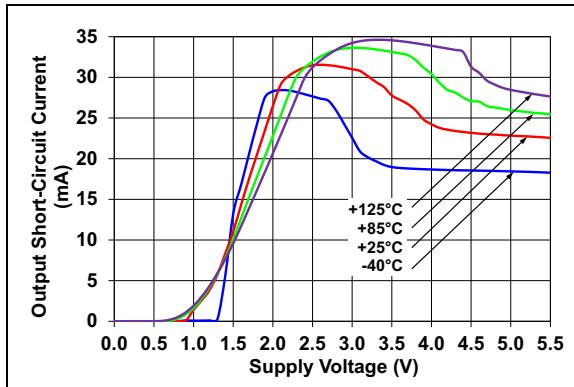


FIGURE 2-15: Output Short-Circuit Current vs. Supply Voltage.

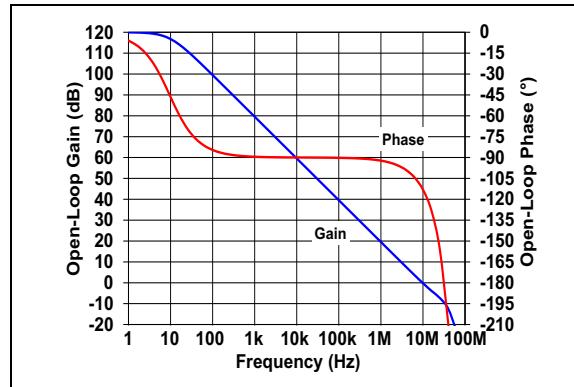


FIGURE 2-18: Open-Loop Gain, Phase vs. Frequency.

MCP6021/1R/2/3/4

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10 \text{ k}\Omega$ to $V_{DD}/2$ and $C_L = 60 \text{ pF}$.

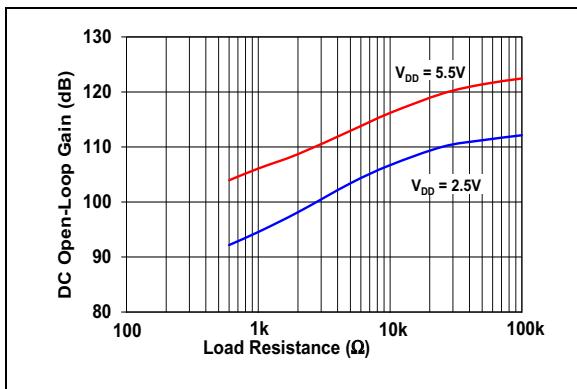


FIGURE 2-19: DC Open-Loop Gain vs. Load Resistance.

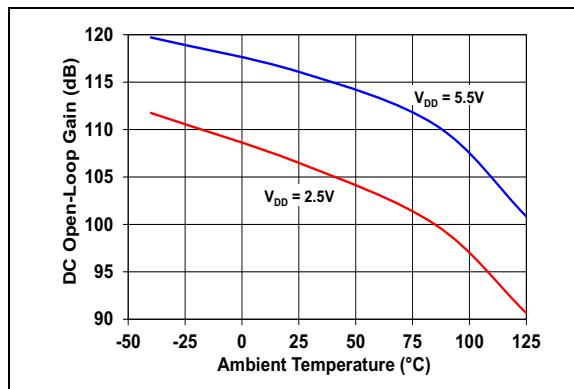


FIGURE 2-22: DC Open-Loop Gain vs. Temperature.

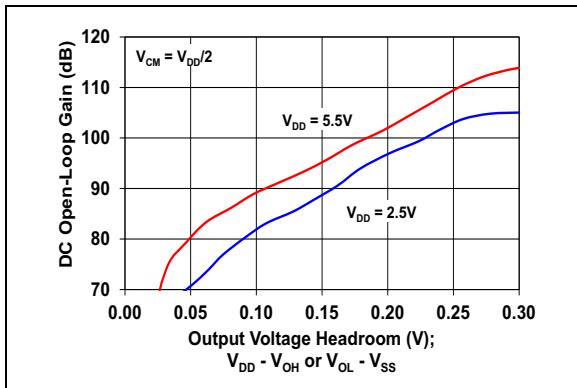


FIGURE 2-20: Small Signal DC Open-Loop Gain vs. Output Voltage Headroom.

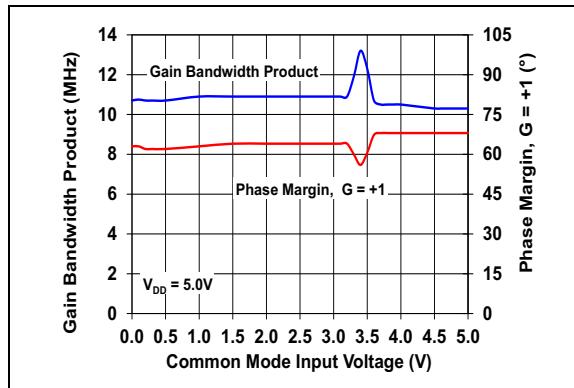


FIGURE 2-23: Gain Bandwidth Product, Phase Margin vs. Common-Mode Input Voltage.

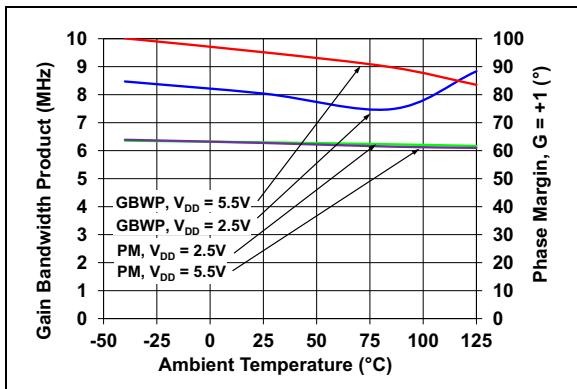


FIGURE 2-21: Gain Bandwidth Product, Phase Margin vs. Temperature.

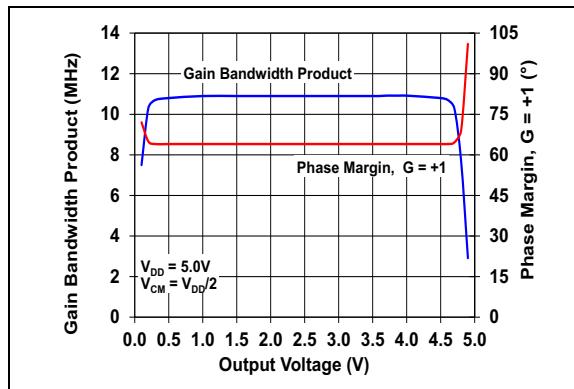


FIGURE 2-24: Gain Bandwidth Product, Phase Margin vs. Output Voltage.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10\text{k}\Omega$ to $V_{DD}/2$ and $C_L = 60\text{ pF}$.

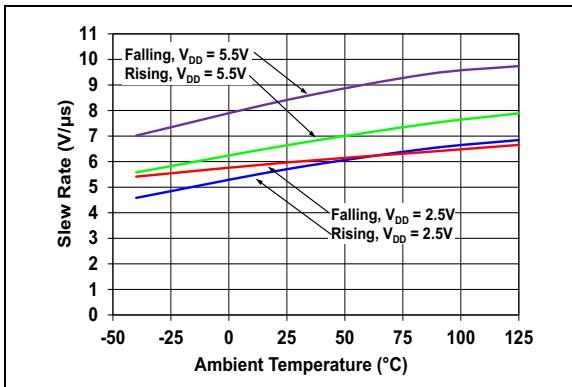


FIGURE 2-25: Slew Rate vs. Temperature.

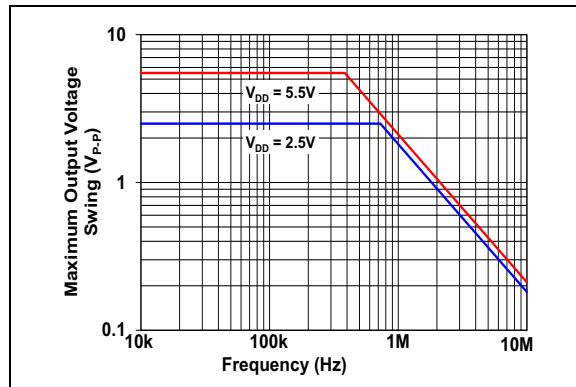


FIGURE 2-28: Maximum Output Voltage Swing vs. Frequency.

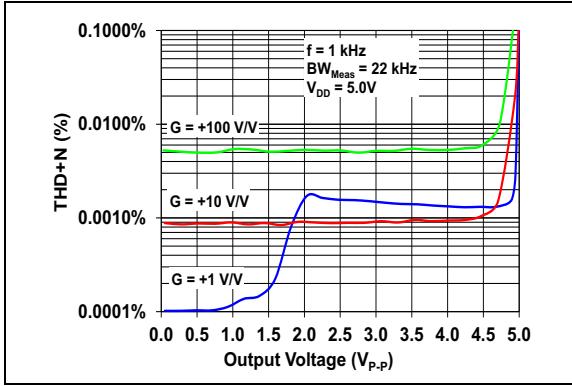


FIGURE 2-26: Total Harmonic Distortion plus Noise vs. Output Voltage with $f = 1\text{ kHz}$.

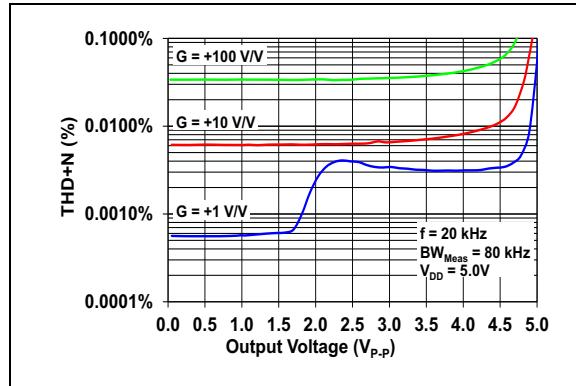


FIGURE 2-29: Total Harmonic Distortion plus Noise vs. Output Voltage with $f = 20\text{ kHz}$.

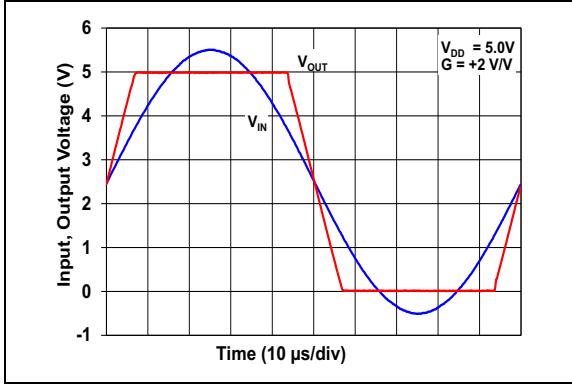


FIGURE 2-27: The MCP6021/1R/2/3/4 Family Shows No Phase Reversal Under Overdrive.

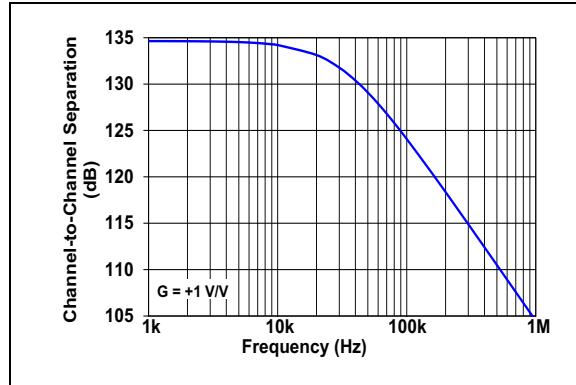


FIGURE 2-30: Channel-to-Channel Separation vs. Frequency (MCP6022 and MCP6024 only).

MCP6021/1R/2/3/4

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10\text{k}\Omega$ to $V_{DD}/2$ and $C_L = 60\text{pF}$.

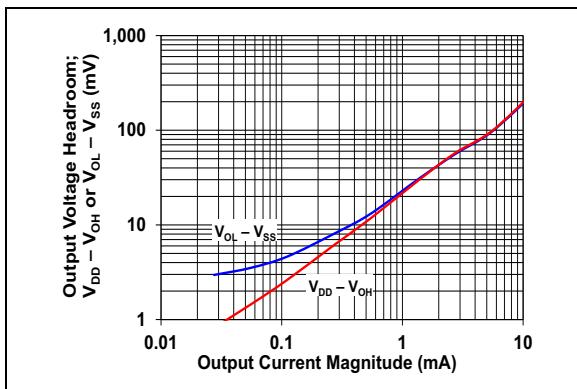


FIGURE 2-31: Output Voltage Headroom vs. Output Current.

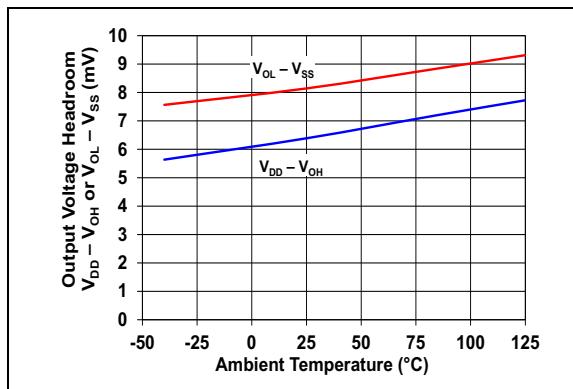


FIGURE 2-34: Output Voltage Headroom vs. Temperature.

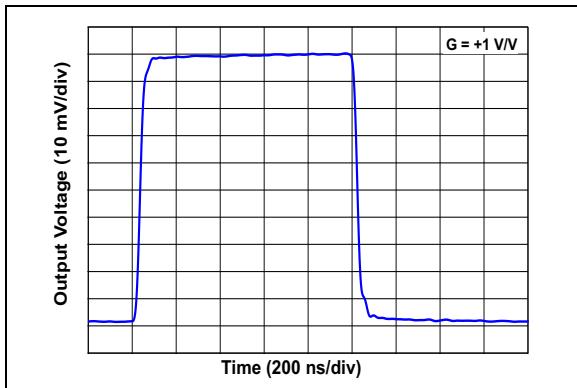


FIGURE 2-32: Small Signal Non-Inverting Pulse Response.

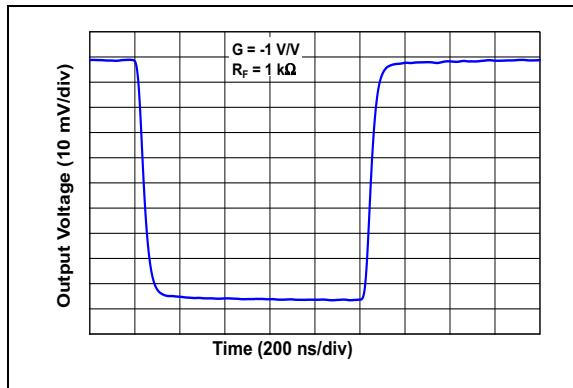


FIGURE 2-35: Small Signal Inverting Pulse Response.

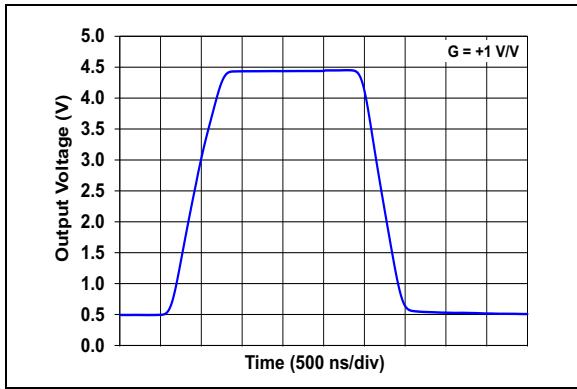


FIGURE 2-33: Large Signal Non-Inverting Pulse Response.

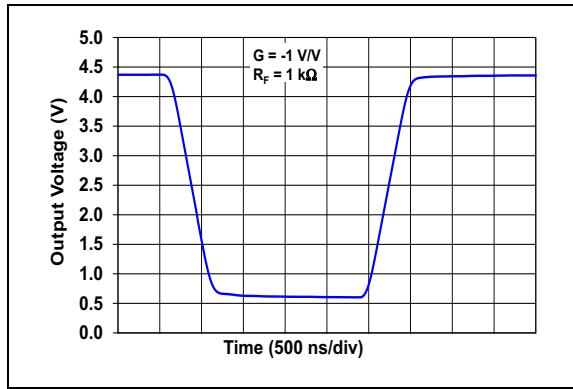


FIGURE 2-36: Large Signal Inverting Pulse Response.

Note: Unless otherwise indicated, $T_A = +25^\circ\text{C}$, $V_{DD} = +2.5\text{V}$ to $+5.5\text{V}$, $V_{SS} = \text{GND}$, $V_{CM} = V_{DD}/2$, $V_{OUT} \approx V_{DD}/2$, $R_L = 10\text{k}\Omega$ to $V_{DD}/2$ and $C_L = 60\text{ pF}$.

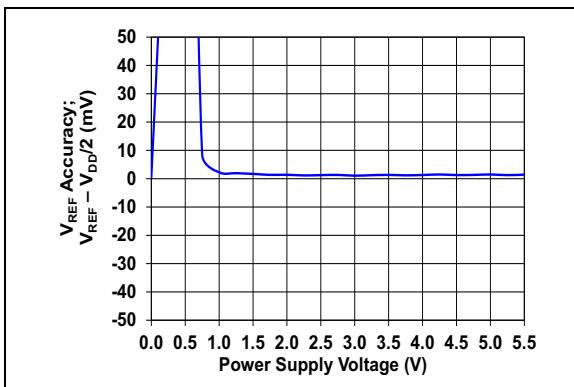


FIGURE 2-37: V_{REF} Accuracy vs. Supply Voltage (MCP6021 and MCP6023 only).

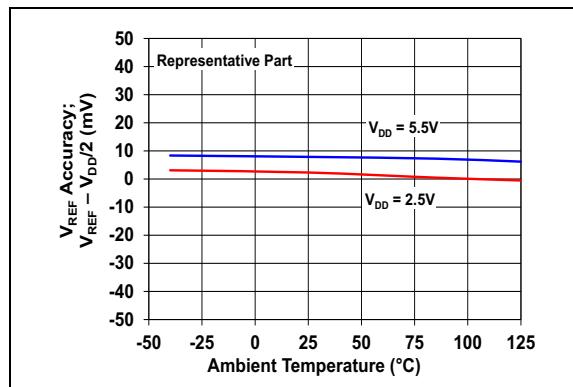


FIGURE 2-40: V_{REF} Accuracy vs. Temperature (MCP6021 and MCP6023 only).

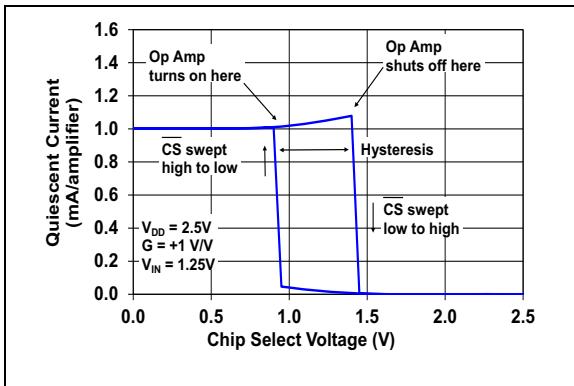


FIGURE 2-38: Chip Select (\overline{CS}) Hysteresis (MCP6023 only) with $V_{DD} = 2.5\text{V}$.

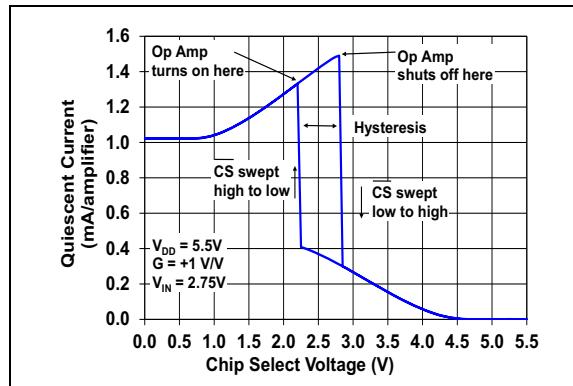


FIGURE 2-41: Chip Select (\overline{CS}) Hysteresis (MCP6023 only) with $V_{DD} = 5.5\text{V}$.

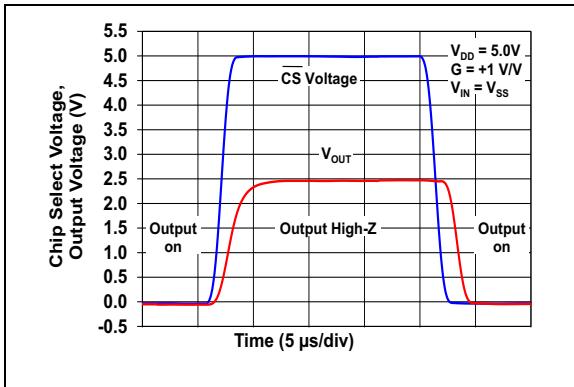


FIGURE 2-39: Chip Select (\overline{CS}) to Amplifier Output Response Time (MCP6023 Only).

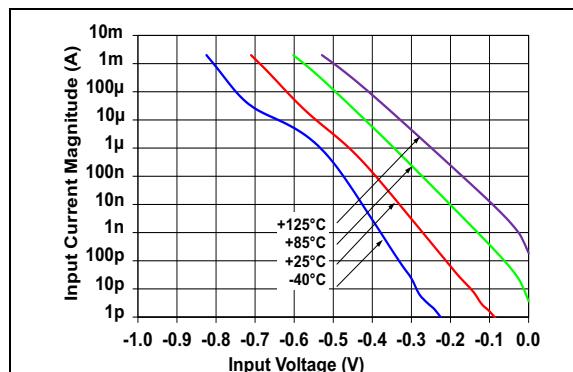


FIGURE 2-42: Measured Input Current vs. Input Voltage (Below V_{SS}).

MCP6021/1R/2/3/4

NOTES:

3.0 PIN DESCRIPTIONS

Descriptions of the pins are listed in [Table 3-1](#).

TABLE 3-1: PIN FUNCTION TABLE

MCP6021		MCP6021	MCP6022	MCP6023	MCP6024	Symbol	Description
PDIP, SOIC, MSOP, TSSOP ⁽¹⁾	SOT-23-5	SOT-23-5 ⁽²⁾	PDIP, SOIC, TSSOP	PDIP, SOIC, TSSOP	PDIP, SOIC, TSSOP		
6	1	1	1	6	1	V_{OUT}, V_{OUTA}	Analog Output (Op Amp A)
2	4	4	2	2	2	V_{IN^-}, V_{INA^-}	Inverting Input (Op Amp A)
3	3	3	3	3	3	V_{IN^+}, V_{INA^+}	Non-Inverting Input (Op Amp A)
7	5	2	8	7	4	V_{DD}	Positive Power Supply
—	—	—	5	—	5	V_{INB^+}	Non-Inverting Input (Op Amp B)
—	—	—	6	—	6	V_{INB^-}	Inverting Input (Op Amp B)
—	—	—	7	—	7	V_{OUTB}	Analog Output (Op Amp B)
—	—	—	—	—	8	V_{OUTC}	Analog Output (Op Amp C)
—	—	—	—	—	9	V_{INC^-}	Inverting Input (Op Amp C)
—	—	—	—	—	10	V_{INC^+}	Non-Inverting Input (Op Amp C)
4	2	5	4	4	11	V_{SS}	Negative Power Supply
—	—	—	—	—	12	V_{IND^+}	Non-Inverting Input (Op Amp D)
—	—	—	—	—	13	V_{IND^-}	Inverting Input (Op Amp D)
—	—	—	—	—	14	V_{OUTD}	Analog Output (Op Amp D)
5	—	—	—	5	—	V_{REF}	Reference Voltage
—	—	—	—	8	—	\overline{CS}	Chip Select
1, 8	—	—	—	1	—	NC	No Internal Connection

Note 1: The MCP6021 in the 8-pin TSSOP package is only available for I-temp (Industrial Temperature) parts.

2: The MCP6021R is only available in the 5-pin SOT-23 package and for E-temp (Extended Temperature) parts.

3.1 Analog Outputs

The operational amplifier output pins are low-impedance voltage sources.

3.2 Analog Inputs

The operational amplifier non-inverting and inverting inputs are high-impedance CMOS inputs with low bias currents.

3.3 Reference Voltage (V_{REF}) MCP6021 and MCP6023

Mid-supply reference voltage is provided by the single operational amplifiers (except in the SOT-23-5 package). This is an unbuffered, resistor voltage divider internal to the part.

3.4 Chip Select Digital Input (\overline{CS})

This is a CMOS, Schmitt triggered input that places the part into a Low-Power mode of operation.

3.5 Power Supply (V_{SS} and V_{DD})

The positive power supply pin (V_{DD}) is 2.5V to 5.5V higher than the negative power supply pin (V_{SS}). For normal operation, the other pins are at voltages between V_{SS} and V_{DD} .

Typically, these parts are used in a single (positive) supply configuration. In this case, V_{SS} is connected to ground and V_{DD} is connected to the supply. V_{DD} will need a bypass capacitor.

MCP6021/1R/2/3/4

NOTES:

4.0 APPLICATIONS INFORMATION

The MCP6021/1R/2/3/4 family of operational amplifiers is fabricated on Microchip's state-of-the-art CMOS process. The amplifiers are unity-gain stable and suitable for a wide range of general purpose applications.

4.1 Rail-to-Rail Input

4.1.1 PHASE REVERSAL

The MCP6021/1R/2/3/4 operational amplifiers are designed to prevent phase reversal when the input pins exceed the supply voltages. [Figure 2-42](#) shows the input voltage exceeding the supply voltage without any phase reversal.

4.1.2 INPUT VOLTAGE LIMITS

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the voltages at the input pins. See the [Absolute Maximum Ratings](#) section.

The ESD protection on the inputs can be depicted as shown in [Figure 4-1](#). This structure was chosen to protect the input transistors and to minimize Input Bias (I_B) current.

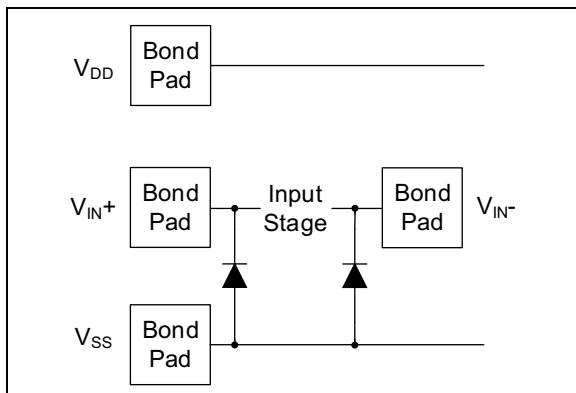


FIGURE 4-1: Simplified Analog Input ESD Structures.

The input ESD diodes clamp the inputs when they try to go more than one diode drop below V_{SS} . They also clamp any voltages that go well above V_{DD} . Their breakdown voltage is high enough to allow normal operation, but not low enough to protect against slow overvoltage (beyond V_{DD}) events. Very fast ESD events (that meet the specifications) are limited so that damage does not occur. In some applications, it may be necessary to prevent excessive voltages from reaching the operational amplifier inputs. [Figure 4-2](#) shows one approach to protecting these inputs.

A significant amount of current can flow out of the inputs when the Common-Mode Voltage (V_{CM}) is below ground (V_{SS}). See [Figure 2-42](#).

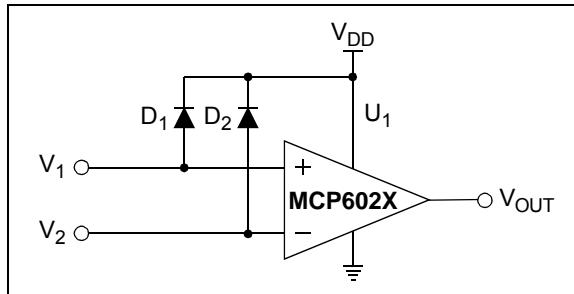


FIGURE 4-2: Protecting the Analog Inputs.

4.1.3 INPUT CURRENT LIMITS

In order to prevent damage and/or improper operation of these amplifiers, the circuit must limit the voltages at the input pins. See the [Absolute Maximum Ratings](#) section. [Figure 4-3](#) shows one approach to protecting these inputs. The resistors, R_1 and R_2 , limit the possible currents in or out of the input pins (and the ESD diodes, D_1 and D_2). The diode currents will go through either V_{DD} or V_{SS} .

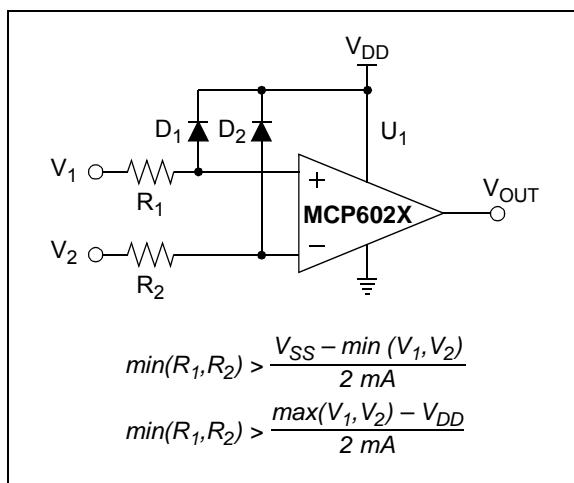


FIGURE 4-3: Protecting the Analog Inputs.

4.1.4 NORMAL OPERATION

The input stage of the MCP6021/1R/2/3/4 operational amplifiers uses two differential CMOS input stages in parallel. One operates at a low Common-Mode Voltage (V_{CM}) input, while the other operates at high V_{CM} . With this topology, the device operates with V_{CM} up to 0.3V above V_{DD} and 0.3V below V_{SS} .

4.2 Rail-to-Rail Output

The maximum output voltage swing is the maximum swing possible under a particular output load. According to the specification table, the output can reach within 20 mV of either supply rail when $R_L = 10 \text{ k}\Omega$. See [Figure 2-31](#) and [Figure 2-34](#) for more information concerning typical performance.

4.3 Capacitive Loads

Driving large capacitive loads can cause stability problems for voltage feedback operational amplifiers. As the load capacitance increases, the feedback loop's phase margin decreases and the closed loop bandwidth is reduced. This produces gain peaking in the frequency response, with overshoot and ringing in the step response.

When driving large capacitive loads with these operational amplifiers (e.g., > 60 pF when $G = +1$), a small series resistor at the output (R_{ISO} in Figure 4-4) improves the feedback loop's phase margin (stability) by making the load resistive at higher frequencies. The bandwidth will be generally lower than the bandwidth with no capacitive load.

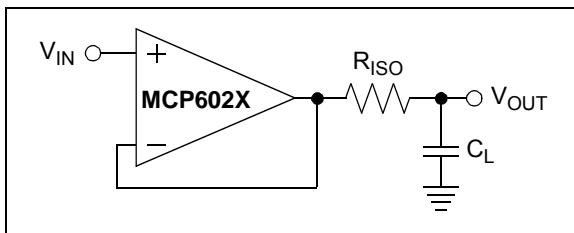


FIGURE 4-4: Output Resistor, R_{ISO} , Stabilizes Large Capacitive Loads.

Figure 4-5 gives recommended R_{ISO} values for different capacitive loads and gains. The x-axis is the normalized load capacitance (C_L/G_N), where G_N is the circuit's noise gain. For non-inverting gains, G_N and the Signal Gain are equal. For inverting gains, G_N is $1+|\text{Signal Gain}|$ (e.g., -1 V/V gives $G_N = +2$ V/V).

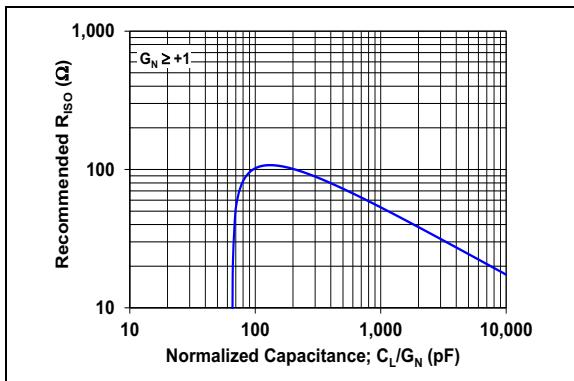


FIGURE 4-5: Recommended R_{ISO} Values for Capacitive Loads.

After selecting R_{ISO} for your circuit, double-check the resulting frequency response peaking and step response overshoot. Modify R_{ISO} 's value until the response is reasonable. Evaluation on the bench and simulations with the MCP6021/1R/2/3/4 Spice macro model are helpful.

4.4 Gain Peaking

Figure 2-35 and Figure 2-36 use $R_F = 1$ kΩ to avoid (frequency response) gain peaking and (step response) overshoot. The capacitance to ground at the inverting input (C_G) is the op amp's Common-mode input capacitance plus board parasitic capacitance. C_G is in parallel with R_G which causes an increase in gain at high frequencies for non-inverting gains greater than 1 V/V (unity gain). C_G also reduces the phase margin of the feedback loop for both non-inverting and inverting gains.

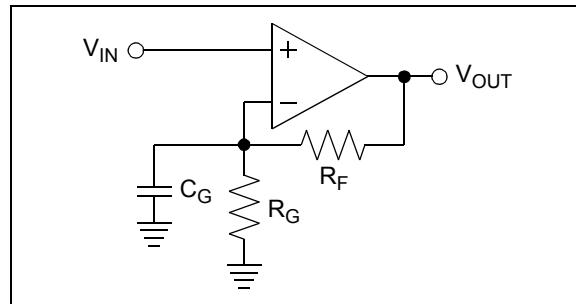


FIGURE 4-6: Non-Inverting Gain Circuit with Parasitic Capacitance.

The largest value of R_F in Figure 4-6 that should be used is a function of noise gain (see G_N in Section 4.3 "Capacitive Loads") and C_G . Figure 4-7 shows results for various conditions. Other compensation techniques may be used, but they tend to be more complicated to design.

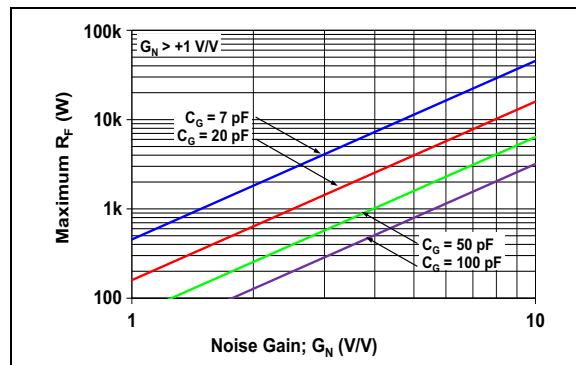


FIGURE 4-7: Non-Inverting Gain Circuit with Parasitic Capacitance.

4.5 MCP6023 Chip Select (CS)

The MCP6023 is a single amplifier with Chip Select (CS). When CS is pulled high, the supply current drops to 10 nA (typical) and flows through the CS pin to V_{SS} . When this happens, the amplifier output is put into a high-impedance state. By pulling CS low, the amplifier is enabled. The CS pin has an internal 5 MΩ (typical) pull-down resistor connected to V_{SS} , so it will go low if the CS pin is left floating. Figure 1-1 and Figure 2-39 show the output voltage and supply current response to a CS pulse.

4.6 MCP6021 and MCP6023 Reference Voltage

The single operational amplifiers (MCP6021 and MCP6023), not in the SOT-23-5 package, have an internal mid-supply reference voltage connected to the V_{REF} pin (see [Figure 4-8](#)). The MCP6021 has CS internally tied to V_{SS} , which always keeps the operational amplifier on and always provides a mid-supply reference. With the MCP6023, taking the CS pin high conserves power by shutting down both the operational amplifier and the V_{REF} circuitry. Taking the CS pin low turns on the operational amplifier and V_{REF} circuitry.

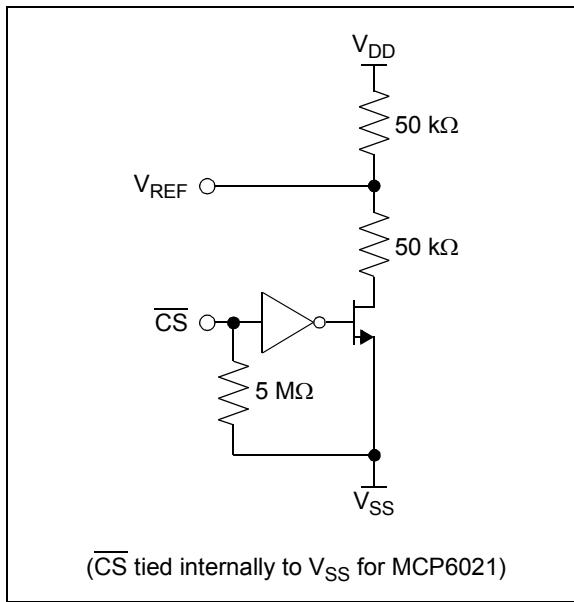


FIGURE 4-8: Simplified Internal V_{REF} Circuit (MCP6021 and MCP6023 only).

See [Figure 4-9](#) for a non-inverting gain circuit using the internal mid-supply reference. The DC Blocking Capacitor (C_B) also reduces noise by coupling the operational amplifier input to the source.

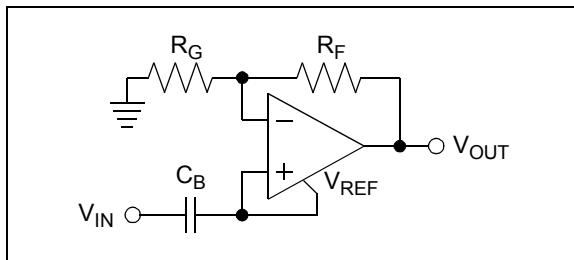


FIGURE 4-9: Non-Inverting Gain Circuit Using V_{REF} (MCP6021 and MCP6023 only).

To use the internal mid-supply reference for an inverting gain circuit, connect the V_{REF} pin to the non-inverting input, as shown in [Figure 4-10](#). The capacitor, C_B , helps reduce power supply noise on the output.

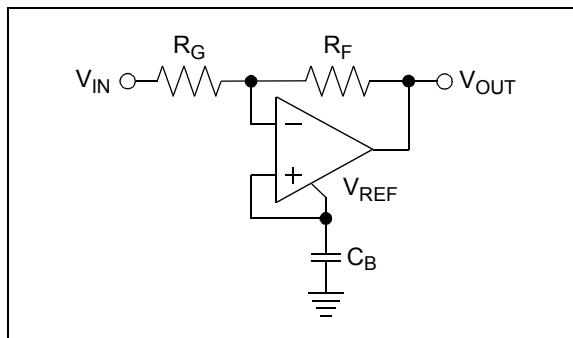


FIGURE 4-10: Inverting Gain Circuit Using V_{REF} (MCP6021 and MCP6023 only).

If you don't need the mid-supply reference, leave the V_{REF} pin open.

4.7 Supply Bypass

With this family of operational amplifiers, the power supply pin (V_{DD} for single supply) should have a local bypass capacitor (i.e., 0.01 μ F to 0.1 μ F) within 2 mm for good, high-frequency performance. It also needs a bulk capacitor (i.e., 1 μ F or larger) within 100 mm to provide large, slow currents. This bulk capacitor can be shared with nearby analog parts.

4.8 Unused Operational Amplifiers

An unused operational amplifier in a quad package (MCP6024) should be configured as shown in [Figure 4-11](#). These circuits prevent the output from toggling and causing crosstalk. Circuit A sets the operational amplifier at its minimum noise gain. The resistor divider produces any desired reference voltage within the output voltage range of the operational amplifier. The operational amplifier buffers that reference voltage. Circuit B uses the minimum number of components and operates as a comparator, but it may draw more current.

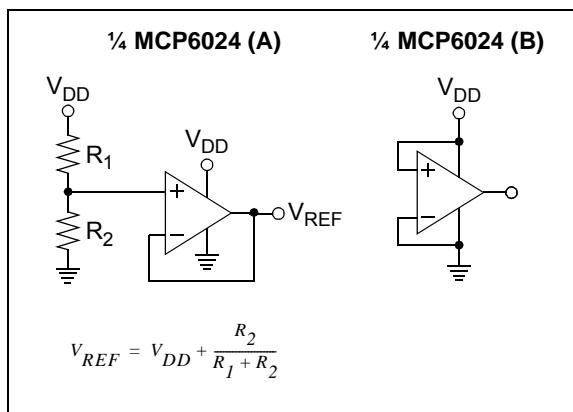


FIGURE 4-11: Unused Operational Amplifiers.

4.9 PCB Surface Leakage

In applications where low input bias current is critical, PCB (Printed Circuit Board) surface leakage effects need to be considered. Surface leakage is caused by humidity, dust or other contamination on the board. Under low humidity conditions, a typical resistance between nearby traces is $10^{12}\Omega$. A 5V difference would cause 5 pA of current to flow, which is greater than the MCP6021/1R/2/3/4 family's bias current at $+25^\circ\text{C}$ (1 pA, typical).

The easiest way to reduce surface leakage is to use a guard ring around sensitive pins (or traces). The guard ring is biased at the same voltage as the sensitive pin. [Figure 4-12](#) shows an example of this type of layout.

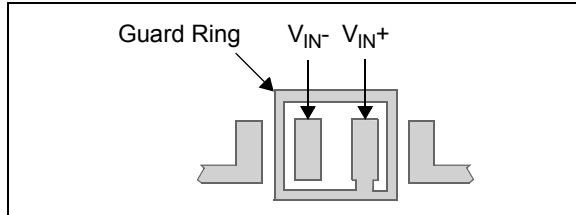


FIGURE 4-12: Example Guard Ring Layout.

1. Non-Inverting Gain and Unity Gain Buffer.
 - a) Connect the guard ring to the inverting input pin (V_{IN^-}); this biases the guard ring to the Common-mode input voltage.
 - b) Connect the non-inverting pin (V_{IN^+}) to the input with a wire that does not touch the PCB surface.
2. Inverting ([Figure 4-12](#)) and Transimpedance Gain Amplifiers (convert current to voltage, such as photo detectors).
 - a) Connect the guard ring to the non-inverting input pin (V_{IN^+}). This biases the guard ring to the same reference voltage as the operational amplifier's input (e.g., $V_{DD}/2$ or ground).
 - b) Connect the inverting pin (V_{IN^-}) to the input with a wire that does not touch the PCB surface.

4.10 High-Speed PCB Layout

Due to their speed capabilities, a little extra care in the PCB (Printed Circuit Board) layout can make a significant difference in the performance of these operational amplifiers. Good PC board layout techniques will help you achieve the performance shown in [Section 1.0 “Electrical Characteristics”](#) and [Section 2.0 “Typical Performance Curves”](#), while also helping you minimize EMC (Electro-Magnetic Compatibility) issues.

Use a solid ground plane and connect the bypass local capacitor(s) to this plane with minimal length traces. This cuts down inductive and capacitive crosstalk.

Separate digital from analog, low speed from high speed and low power from high power. This will reduce interference.

Keep sensitive traces short and straight. Separate them from interfering components and traces. This is especially important for high-frequency (low rise time) signals.

Sometimes it helps to place guard traces next to victim traces. They should be on both sides of the victim trace and as close as possible. Connect the guard trace to the ground plane at both ends and in the middle for long traces.

Use coax cables (or low-inductance wiring) to route signal and power to and from the PCB.

4.11 Typical Applications

4.11.1 A/D CONVERTER DRIVER AND ANTI-ALIASING FILTER

[Figure 4-13](#) shows a third-order Butterworth filter that can be used as an A/D Converter driver. It has a bandwidth of 20 kHz and a reasonable step response. It will work well for conversion rates of 80 ksps and greater (it has 29 dB attenuation at 60 kHz).

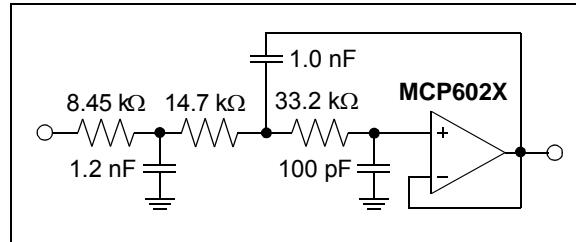


FIGURE 4-13: A/D Converter Driver and Anti-Aliasing Filter with a 20 kHz Cutoff Frequency.

This filter can easily be adjusted to another bandwidth by multiplying all capacitors by the same factor. Alternatively, the resistors can all be scaled by another common factor to adjust the bandwidth.

4.11.2 OPTICAL DETECTOR AMPLIFIER

Figure 4-14 shows the MCP6021 operational amplifier used as a transimpedance amplifier in a photo detector circuit. The photo detector looks like a capacitive current source, so the 100 k Ω resistor gains the input signal to a reasonable level. The 5.6 pF capacitor stabilizes this circuit and produces a flat frequency response with a bandwidth of 370 kHz.

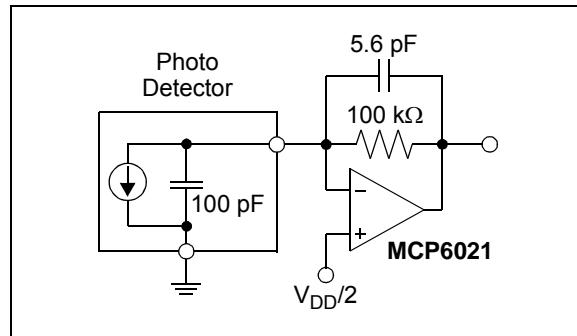


FIGURE 4-14: Transimpedance Amplifier for an Optical Detector.

MCP6021/1R/2/3/4

NOTES:

5.0 DESIGN AIDS

Microchip provides the basic design tools needed for the MCP6021/1R/2/3/4 family of operational amplifiers.

5.1 SPICE Macro Model

The latest SPICE macro model available for the MCP6021/1R/2/3/4 operational amplifiers is on Microchip's web site at www.microchip.com. This model is intended as an initial design tool that works well in the operational amplifier's linear region of operation at room temperature. There is information on its capabilities within the macro model file.

Bench testing is a very important part of any design and cannot be replaced with simulations. Also, simulation results using this macro model need to be validated by comparing them to the data sheet specifications and characteristic curves.

5.2 FilterLab® Software

Microchip's FilterLab® software is an innovative software tool that simplifies analog active filter (using operational amplifiers) design. Available at no cost from the Microchip web site at www.microchip.com/filterlab, the FilterLab design tool provides full schematic diagrams of the filter circuit with component values. It also outputs the filter circuit in SPICE format, which can be used with the macro model to simulate actual filter performance.

5.3 MPLAB® Mindi™ Analog Simulator

Microchip's Mindi™ circuit designer and simulator aids in the design of various circuits useful for active filter, amplifier and power management applications. It is a free online circuit designer and simulator available from the Microchip web site at www.microchip.com/mindi. This interactive circuit designer and simulator enables designers to quickly generate circuit diagrams and simulate circuits. Circuits developed using the MPLAB Mindi analog simulator can be downloaded to a personal computer or workstation.

5.4 Microchip Advanced Part Selector (MAPS)

MAPS is a software tool that helps semiconductor professionals efficiently identify Microchip devices that fit a particular design requirement. Available at no cost from the Microchip web site at www.microchip.com/maps, the MAPS is an overall selection tool for Microchip's product portfolio, that includes analog, memory, MCUs and DSCs. Using this tool you can define a filter to sort features for a parametric search of devices and export side-by-side technical comparison reports. Helpful links are also provided for data sheets, purchasing and sampling of Microchip parts.

5.5 Analog Demonstration and Evaluation Boards

Microchip offers a broad spectrum of analog demonstration and evaluation boards that are designed to help you achieve faster time to market. For a complete listing of these boards, and their corresponding user's guides and technical information, visit the Microchip web site at www.microchip.com/analogtools.

Some boards that are especially useful are:

- MCP6XXX Amplifier Evaluation Board 1
- MCP6XXX Amplifier Evaluation Board 2
- MCP6XXX Amplifier Evaluation Board 3
- MCP6XXX Amplifier Evaluation Board 4
- Active Filter Demo Board Kit
- 8-Pin SOIC/MSOP/TSSOP/DIP Evaluation Board, P/N: SOIC8EV
- 14-Pin SOIC/TSSOP/DIP Evaluation Board, P/N: SOIC14EV

5.6 Application Notes

The following Microchip Application Notes are available on the Microchip web site at www.microchip.com/appnotes and are recommended as supplemental reference resources.

- ADN003, "Select the Right Operational Amplifier for your Filtering Circuits" (DS21821)
- AN722, "Operational Amplifier Topologies and DC Specifications" (DS00722)
- AN723, "Operational Amplifier AC Specifications and Applications" (DS00723)
- AN884, "Driving Capacitive Loads With Op Amps" (DS00884)
- AN990, "Analog Sensor Conditioning Circuits – An Overview" (DS00990)
- AN1177, "Op Amp Precision Design: DC Errors" (DS01177)
- AN1228, "Op Amp Precision Design: Random Noise" (DS01228)

These application notes and others are listed in the design guide: "Signal Chain Design Guide" (DS21825).

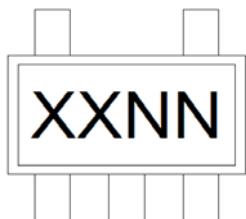
MCP6021/1R/2/3/4

NOTES:

6.0 PACKAGING INFORMATION

6.1 Package Marking Information

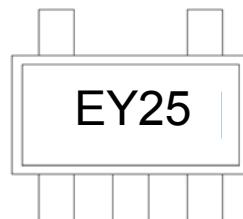
5-Lead SOT-23 (MCP6021/MCP6021R)



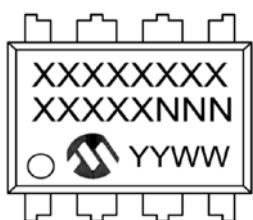
Device	E-Temp Code
MCP6021	EYNN
MCP6021R	EZNN

Note: Applies to 5-Lead SOT-23.

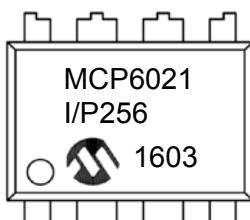
Example:



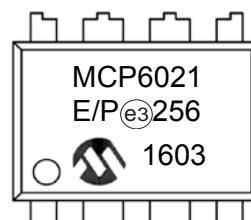
8-Lead PDIP (300 mil)



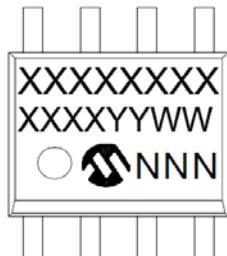
Example:



OR



8-Lead SOIC (150 mil)



Example:



OR



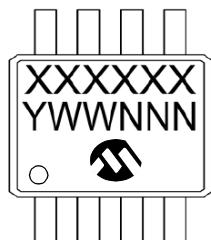
Legend:	XX...X Customer-specific information
Y	Year code (last digit of calendar year)
YY	Year code (last 2 digits of calendar year)
WW	Week code (week of January 1 is week '01')
NNN	Alphanumeric traceability code
(e3)	Pb-free JEDEC® designator for Matte Tin (Sn)
*	This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.

Note: In the event the full Microchip part number cannot be marked on one line, it will be carried over to the next line, thus limiting the number of available characters for customer-specific information.

MCP6021/1R/2/3/4

Package Marking Information (Continued)

8-Lead MSOP



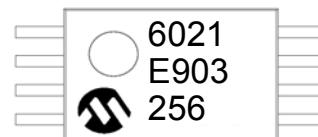
Example:



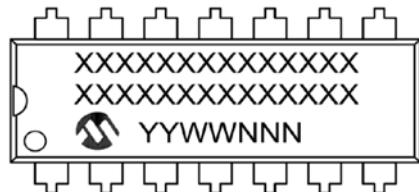
8-Lead TSSOP



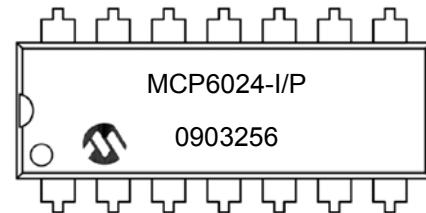
Example:



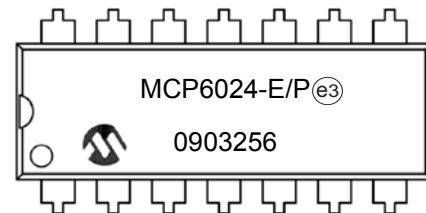
14-Lead PDIP (300 mil) (**MCP6024**)



Example:

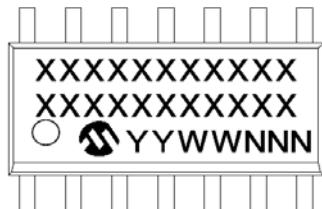


OR

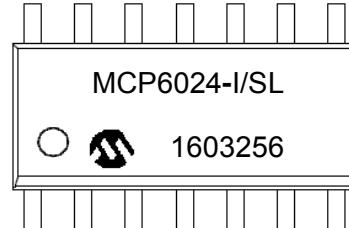


Package Marking Information (Continued)

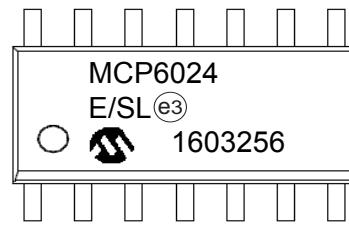
14-Lead SOIC (150 mil) (**MCP6024**)



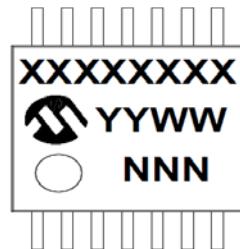
Example:



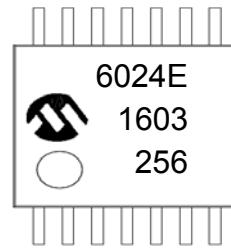
OR



14-Lead TSSOP (**MCP6024**)



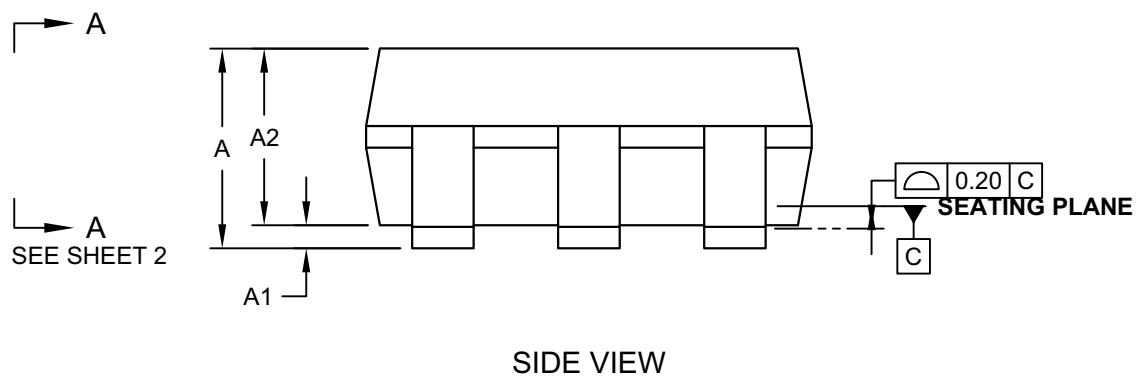
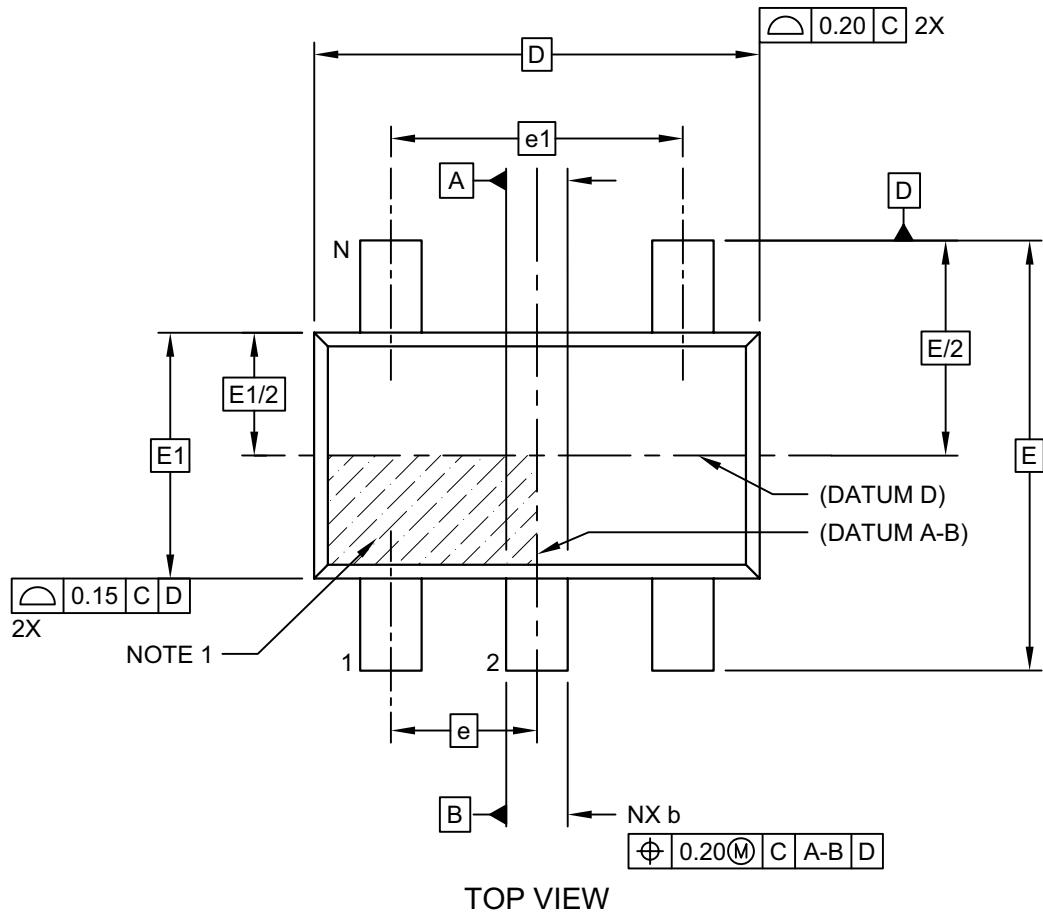
Example:



MCP6021/1R/2/3/4

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

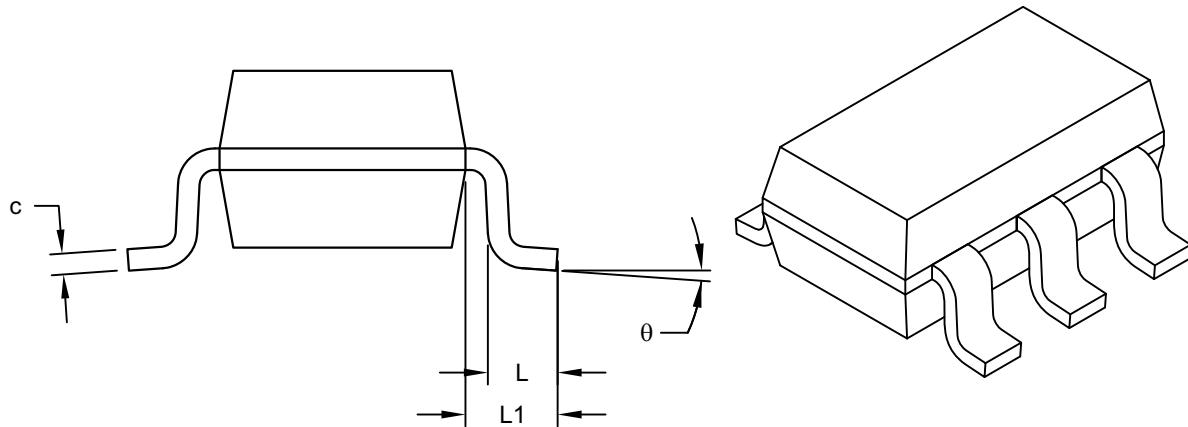
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing C04-028D [OT] Sheet 1 of 2

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



VIEW A-A
SHEET 1

Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Number of Pins	N		6	
Pitch	e		0.95 BSC	
Outside lead pitch	e1		1.90 BSC	
Overall Height	A	0.90	-	1.45
Molded Package Thickness	A2	0.89	-	1.30
Standoff	A1	-	-	0.15
Overall Width	E	2.80 BSC		
Molded Package Width	E1	1.60 BSC		
Overall Length	D	2.90 BSC		
Foot Length	L	0.30	-	0.60
Footprint	L1	0.60 REF		
Foot Angle	ϕ	0°	-	10°
Lead Thickness	c	0.08	-	0.26
Lead Width	b	0.20	-	0.51

Notes:

1. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.25mm per side.

2. Dimensioning and tolerancing per ASME Y14.5M

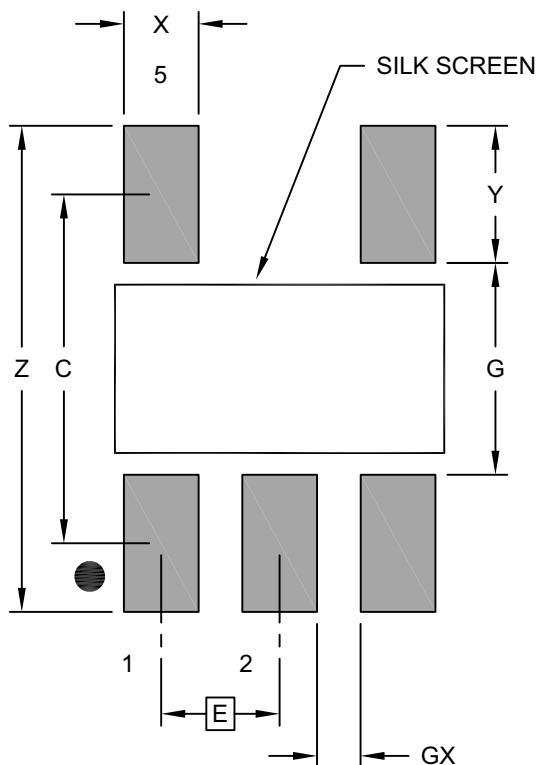
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

MCP6021/1R/2/3/4

5-Lead Plastic Small Outline Transistor (OT) [SOT23]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension	Limits	MIN	NOM	MAX
Contact Pitch	E		0.95	BSC
Contact Pad Spacing	C		2.80	
Contact Pad Width (X5)	X			0.60
Contact Pad Length (X5)	Y			1.10
Distance Between Pads	G	1.70		
Distance Between Pads	GX	0.35		
Overall Width	Z			3.90

Notes:

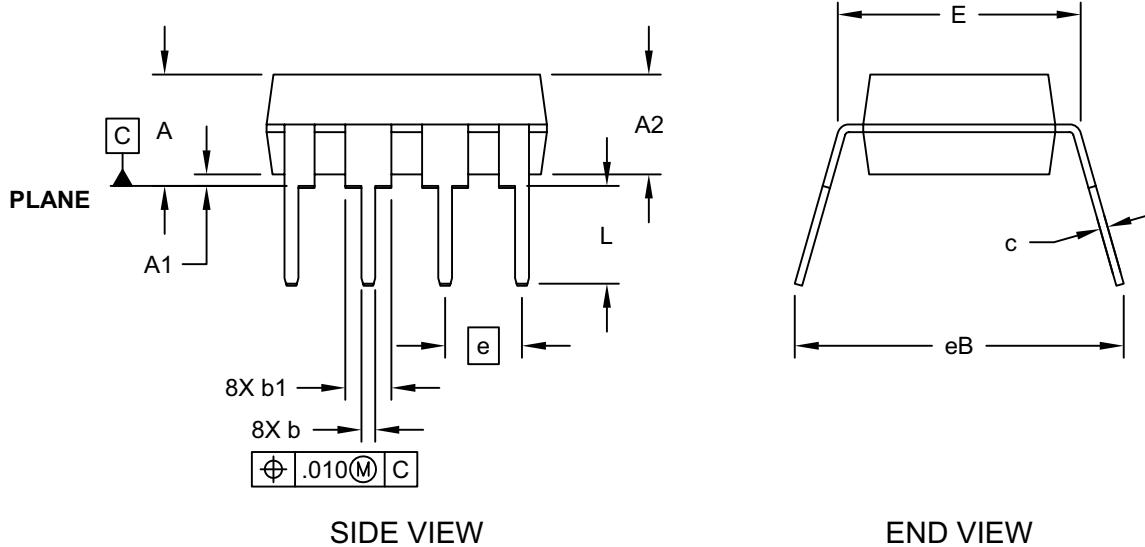
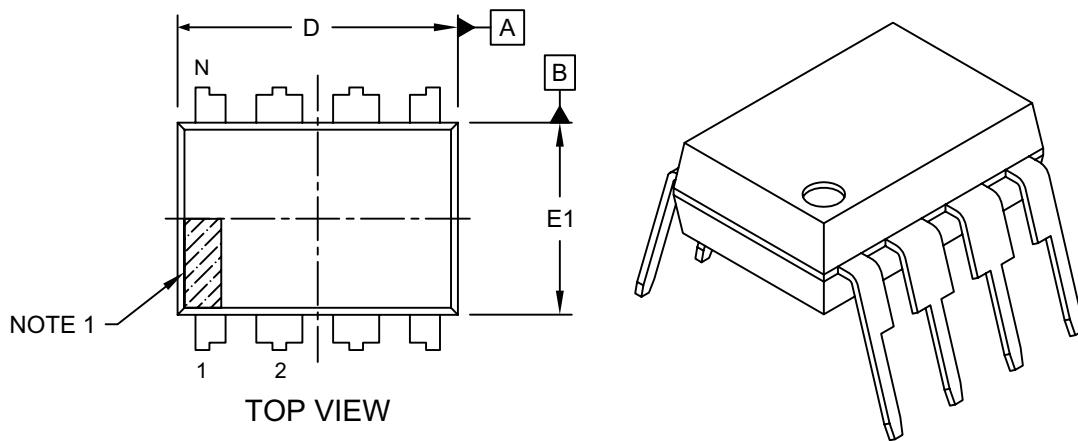
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2091A [OT]

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

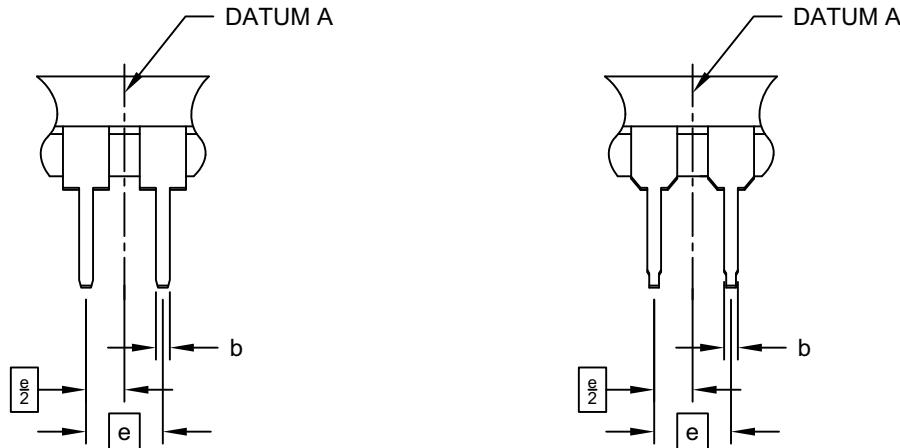


MCP6021/1R/2/3/4

8-Lead Plastic Dual In-Line (P) - 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

ALTERNATE LEAD DESIGN (VENDOR DEPENDENT)



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins		N		8
Pitch		e		.100 BSC
Top to Seating Plane	A	-	-	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	-	-
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.348	.365	.400
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.040	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing	§	eB	-	.430

Notes:

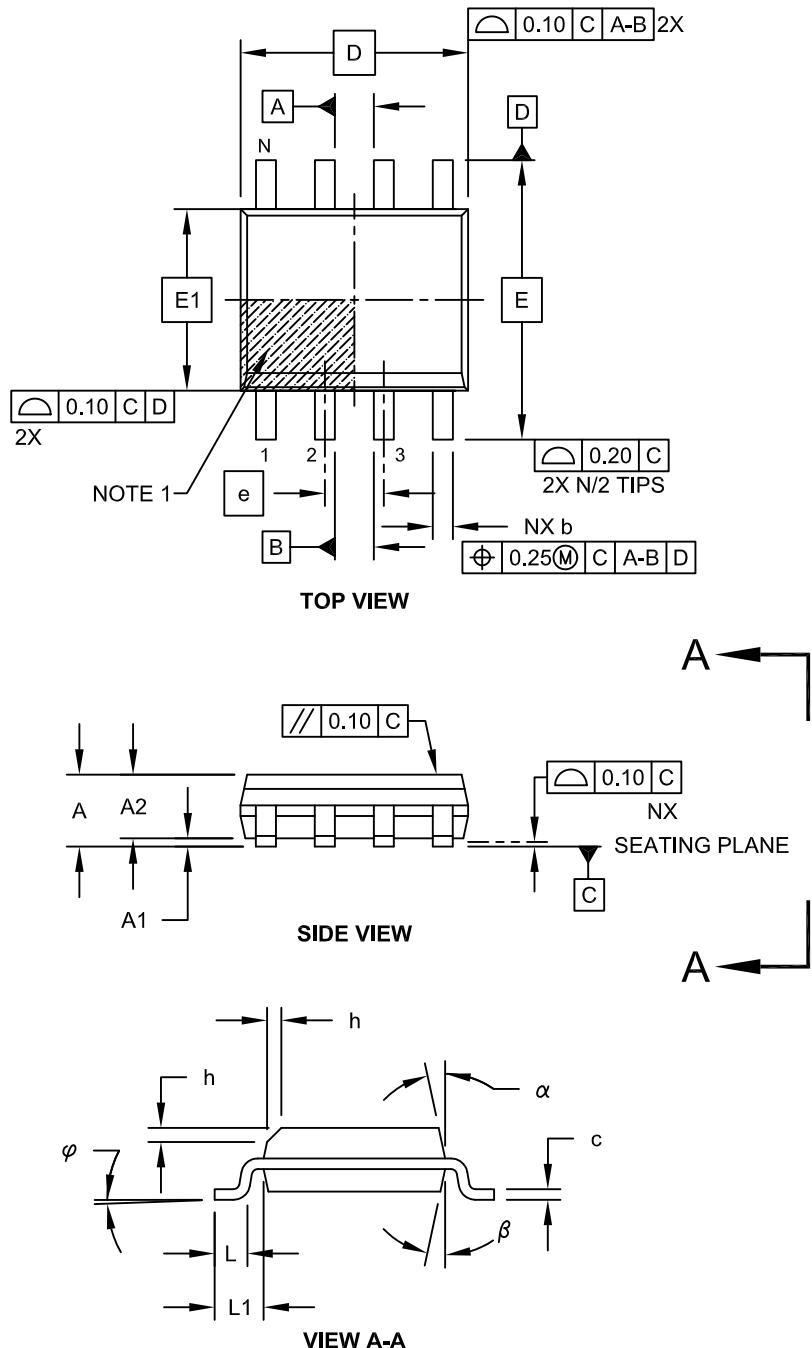
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-018D Sheet 2 of 2

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

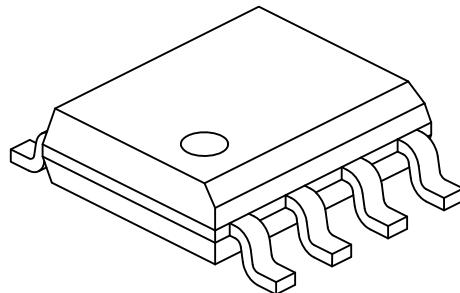


Microchip Technology Drawing No. C04-057C Sheet 1 of 2

MCP6021/1R/2/3/4

8-Lead Plastic Small Outline (SN) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension	Limits	Units MILLIMETERS		
		MIN	NOM	MAX
Number of Pins	N	8		
Pitch	e	1.27	BSC	
Overall Height	A	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff	§	A1	0.10	-
Overall Width	E	6.00	BSC	
Molded Package Width	E1	3.90	BSC	
Overall Length	D	4.90	BSC	
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1	1.04	REF	
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.17	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. § Significant Characteristic
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
4. Dimensioning and tolerancing per ASME Y14.5M

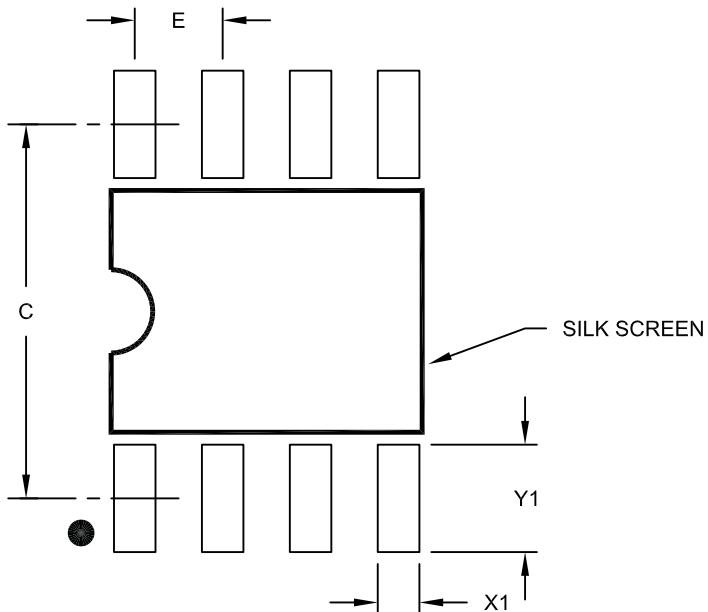
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

Microchip Technology Drawing No. C04-057C Sheet 2 of 2

8-Lead Plastic Small Outline (SN) – Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits		Units	MILLIMETERS		
			MIN	NOM	MAX
Contact Pitch	E		1.27	BSC	
Contact Pad Spacing	C		5.40		
Contact Pad Width (X8)	X1			0.60	
Contact Pad Length (X8)	Y1				1.55

Notes:

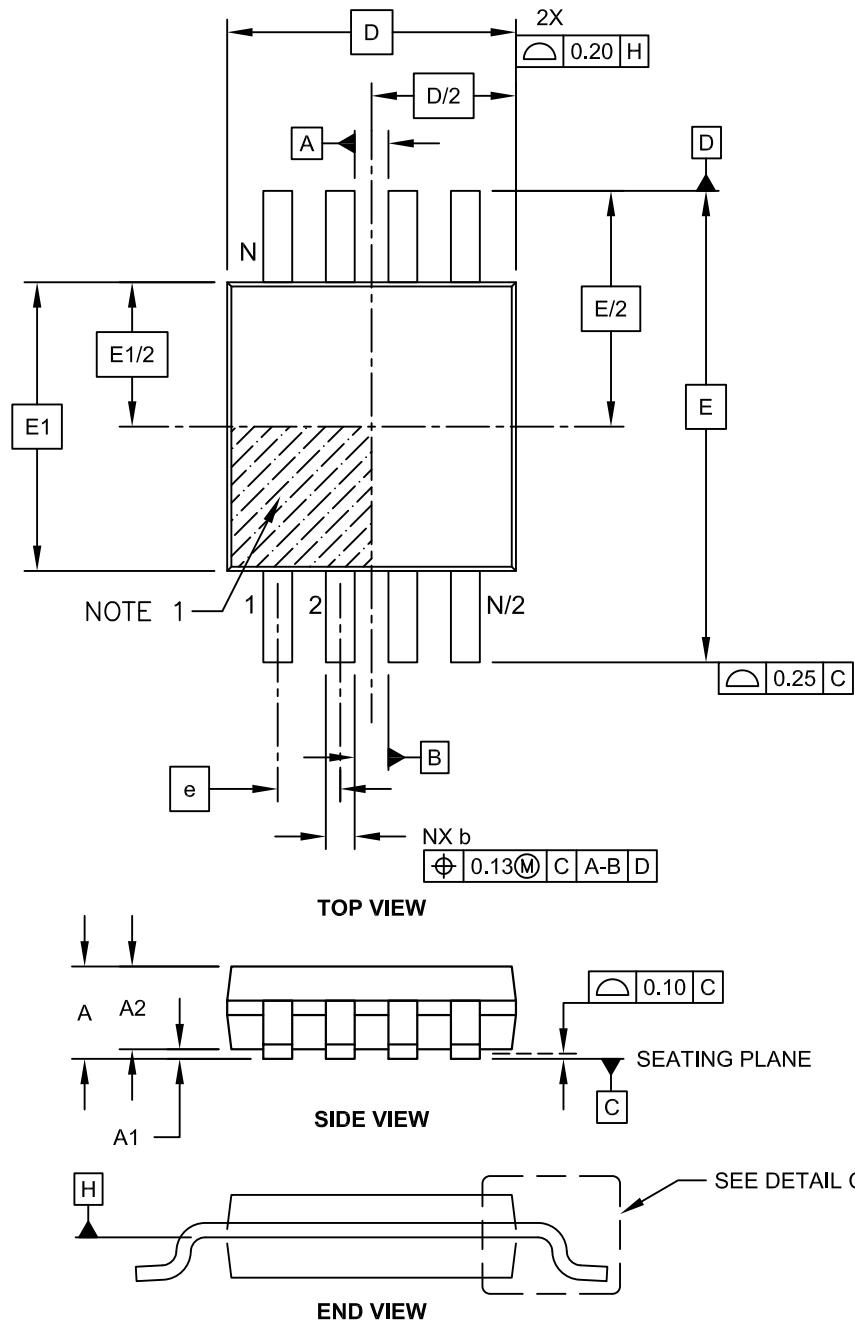
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2057A

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

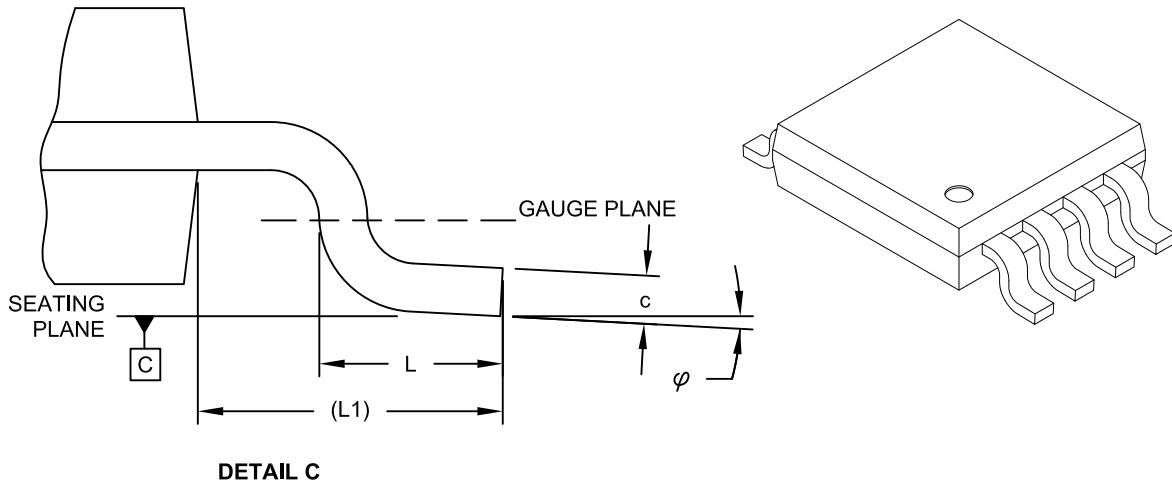
Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Microchip Technology Drawing C04-111C Sheet 1 of 2

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Dimension	Limits	Units		
		MILLIMETERS		
Number of Pins	N		8	
Pitch	e		0.65	BSC
Overall Height	A	-	-	1.10
Molded Package Thickness	A2	0.75	0.85	0.95
Standoff	A1	0.00	-	0.15
Overall Width	E		4.90	BSC
Molded Package Width	E1		3.00	BSC
Overall Length	D		3.00	BSC
Foot Length	L	0.40	0.60	0.80
Footprint	L1		0.95	REF
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.08	-	0.23
Lead Width	b	0.22	-	0.40

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.

3. Dimensioning and tolerancing per ASME Y14.5M.

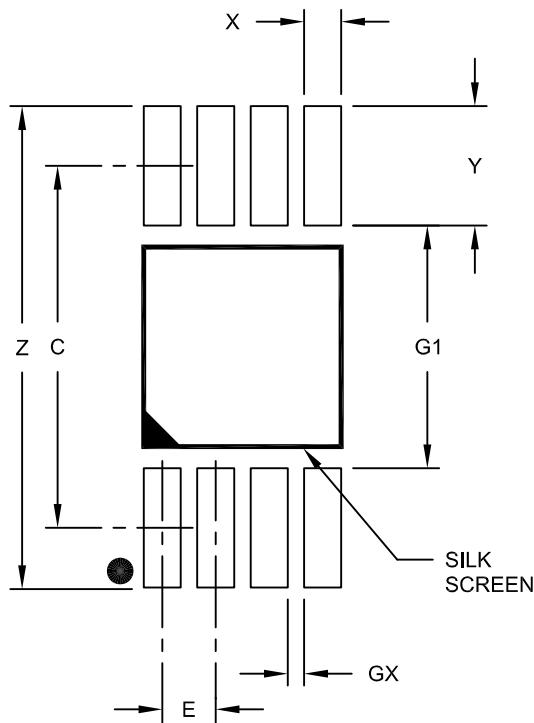
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

MCP6021/1R/2/3/4

8-Lead Plastic Micro Small Outline Package (MS) [MSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C		4.40	
Overall Width	Z			5.85
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G1	2.95		
Distance Between Pads	GX	0.20		

Notes:

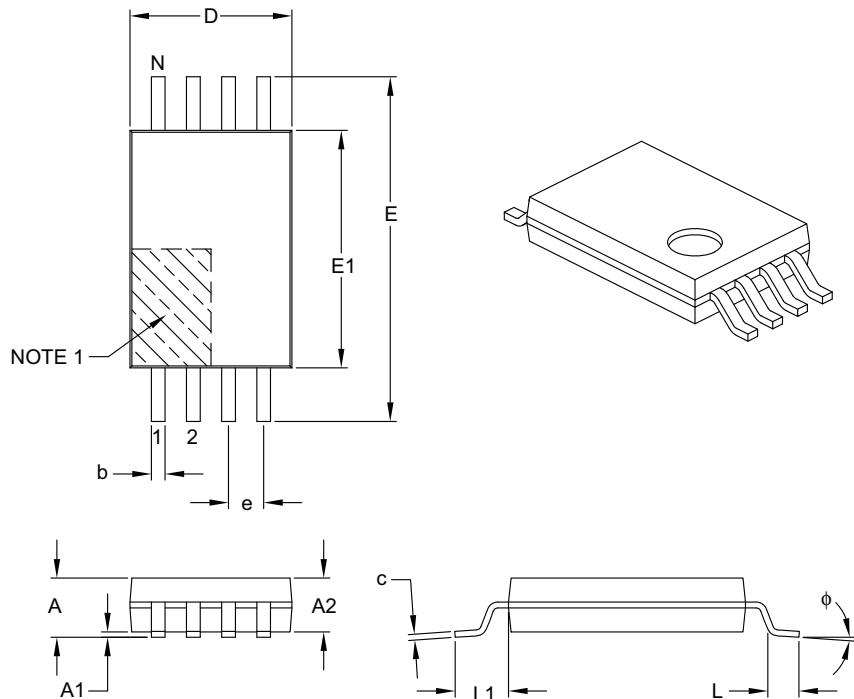
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2111A

8-Lead Plastic Thin Shrink Small Outline (ST) – 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		8	
Pitch	e		0.65 BSC	
Overall Height	A	—	—	1.20
Molded Package Thickness	A2	0.80	1.00	1.05
Standoff	A1	0.05	—	0.15
Overall Width	E		6.40 BSC	
Molded Package Width	E1	4.30	4.40	4.50
Molded Package Length	D	2.90	3.00	3.10
Foot Length	L	0.45	0.60	0.75
Footprint	L1		1.00 REF	
Foot Angle	ϕ	0°	—	8°
Lead Thickness	c	0.09	—	0.20
Lead Width	b	0.19	—	0.30

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15 mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M.

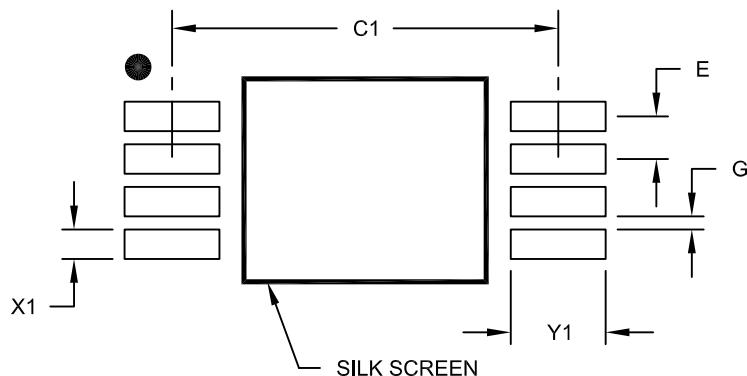
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

MCP6021/1R/2/3/4

8-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits		MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E		0.65 BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X8)	X1			0.45
Contact Pad Length (X8)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

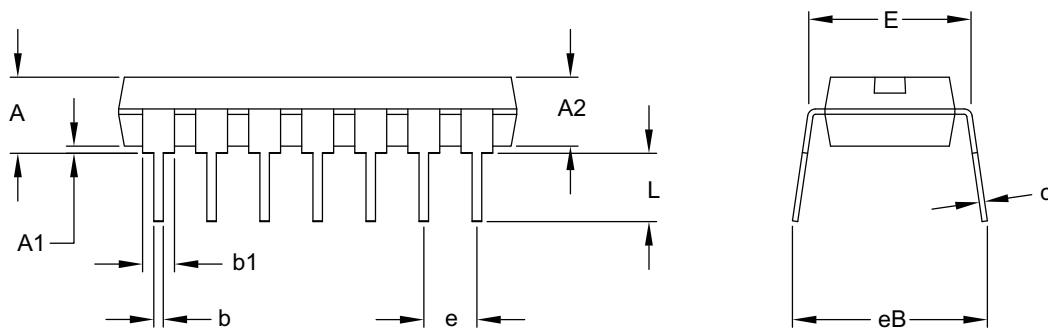
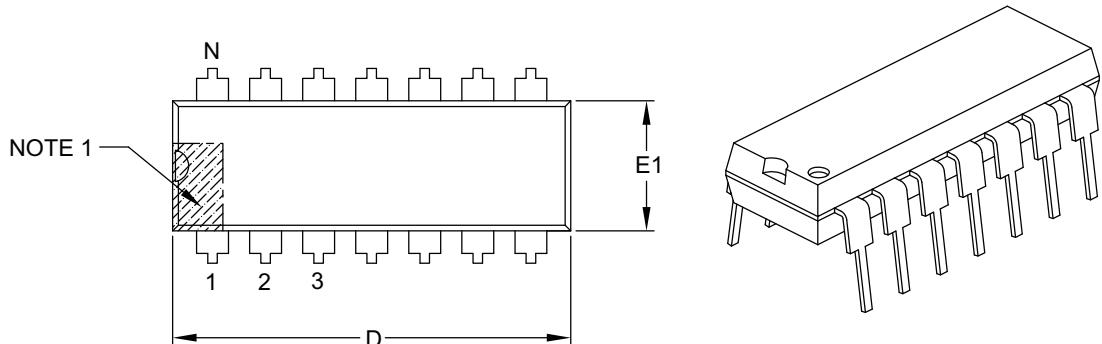
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2086A

14-Lead Plastic Dual In-Line (P) – 300 mil Body [PDIP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		INCHES		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N		14	
Pitch	e		.100 BSC	
Top to Seating Plane	A	—	—	.210
Molded Package Thickness	A2	.115	.130	.195
Base to Seating Plane	A1	.015	—	—
Shoulder to Shoulder Width	E	.290	.310	.325
Molded Package Width	E1	.240	.250	.280
Overall Length	D	.735	.750	.775
Tip to Seating Plane	L	.115	.130	.150
Lead Thickness	c	.008	.010	.015
Upper Lead Width	b1	.045	.060	.070
Lower Lead Width	b	.014	.018	.022
Overall Row Spacing §	eB	—	—	.430

Notes:

1. Pin 1 visual index feature may vary, but must be located with the hatched area.
2. § Significant Characteristic.
3. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed .010" per side.
4. Dimensioning and tolerancing per ASME Y14.5M.

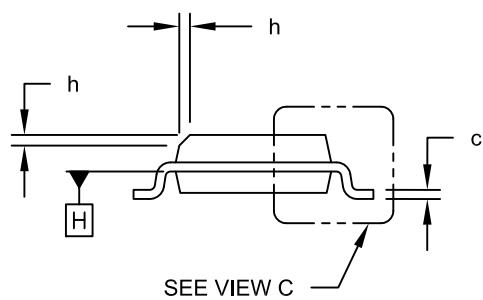
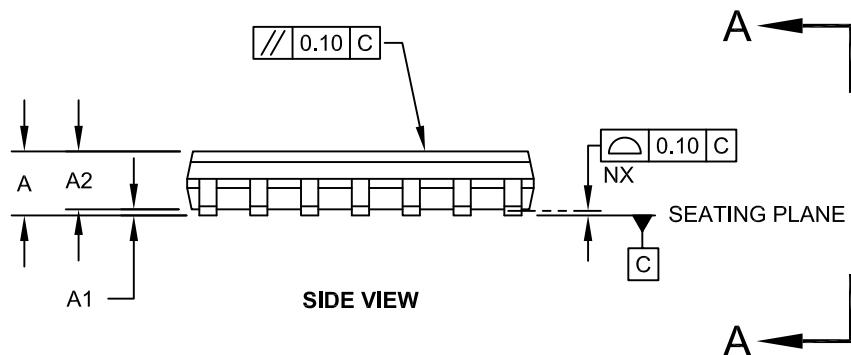
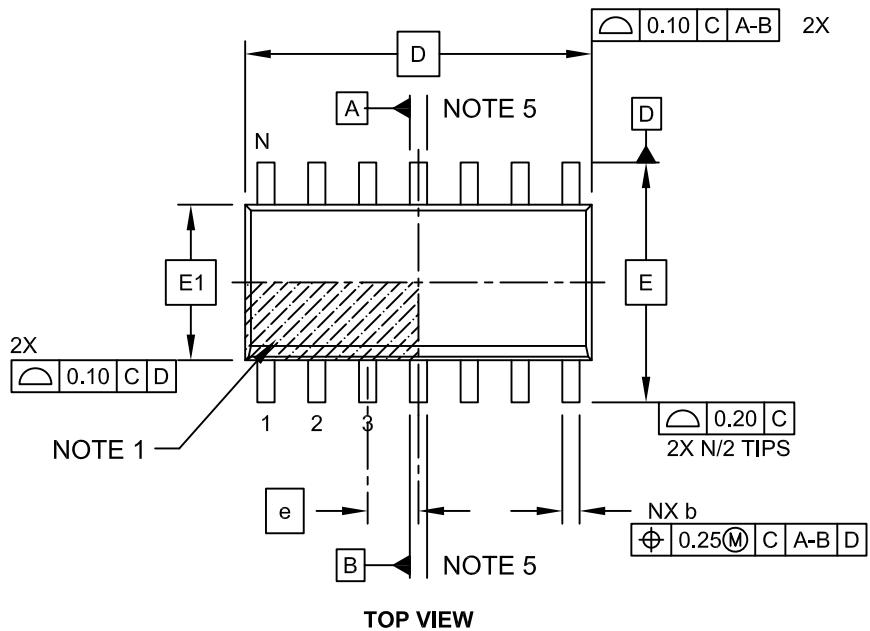
BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing C04-005B

MCP6021/1R/2/3/4

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

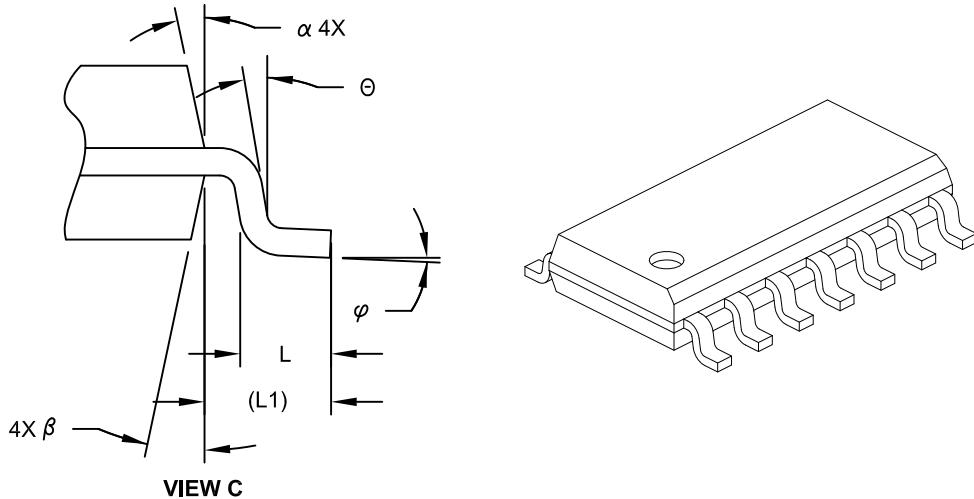


VIEW A-A

Microchip Technology Drawing No. C04-065C Sheet 1 of 2

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins	N	14		
Pitch	e	1.27	BSC	
Overall Height	A	-	-	1.75
Molded Package Thickness	A2	1.25	-	-
Standoff §	A1	0.10	-	0.25
Overall Width	E	6.00	BSC	
Molded Package Width	E1	3.90	BSC	
Overall Length	D	8.65	BSC	
Chamfer (Optional)	h	0.25	-	0.50
Foot Length	L	0.40	-	1.27
Footprint	L1	1.04	REF	
Lead Angle	θ	0°	-	-
Foot Angle	φ	0°	-	8°
Lead Thickness	c	0.10	-	0.25
Lead Width	b	0.31	-	0.51
Mold Draft Angle Top	α	5°	-	15°
Mold Draft Angle Bottom	β	5°	-	15°

Notes:

1. Pin 1 visual index feature may vary, but must be located within the hatched area.

2. § Significant Characteristic

3. Dimension D does not include mold flash, protrusions or gate burrs, which shall not exceed 0.15 mm per end. Dimension E1 does not include interlead flash or protrusion, which shall not exceed 0.25 mm per side.

4. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

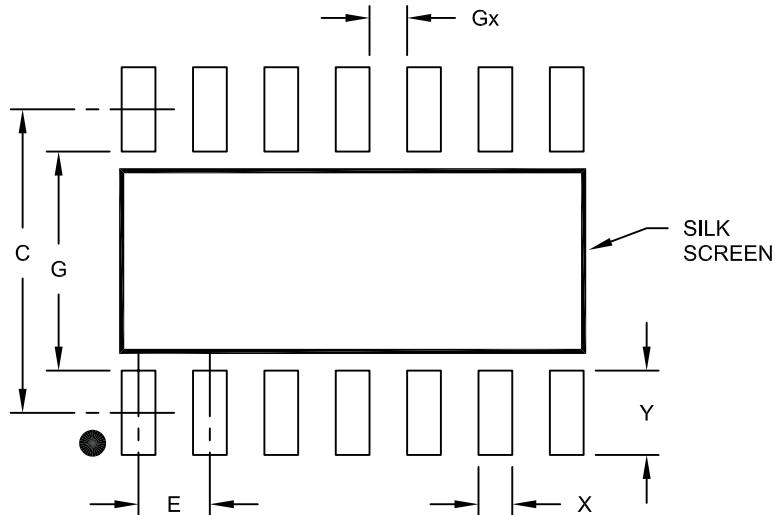
REF: Reference Dimension, usually without tolerance, for information purposes only.

5. Datums A & B to be determined at Datum H.

MCP6021/1R/2/3/4

14-Lead Plastic Small Outline (SL) - Narrow, 3.90 mm Body [SOIC]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits		MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E		1.27 BSC	
Contact Pad Spacing	C		5.40	
Contact Pad Width	X			0.60
Contact Pad Length	Y			1.50
Distance Between Pads	Gx	0.67		
Distance Between Pads	G	3.90		

Notes:

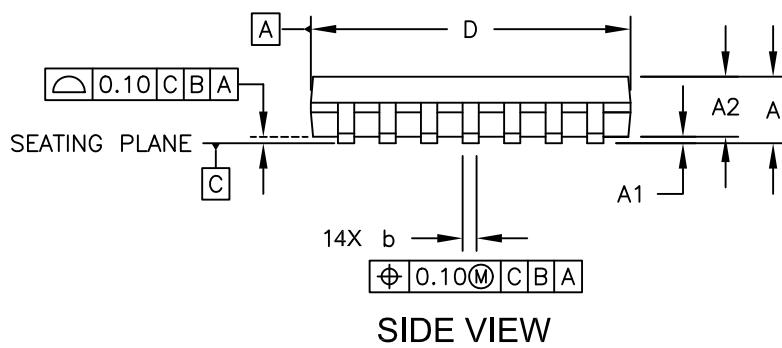
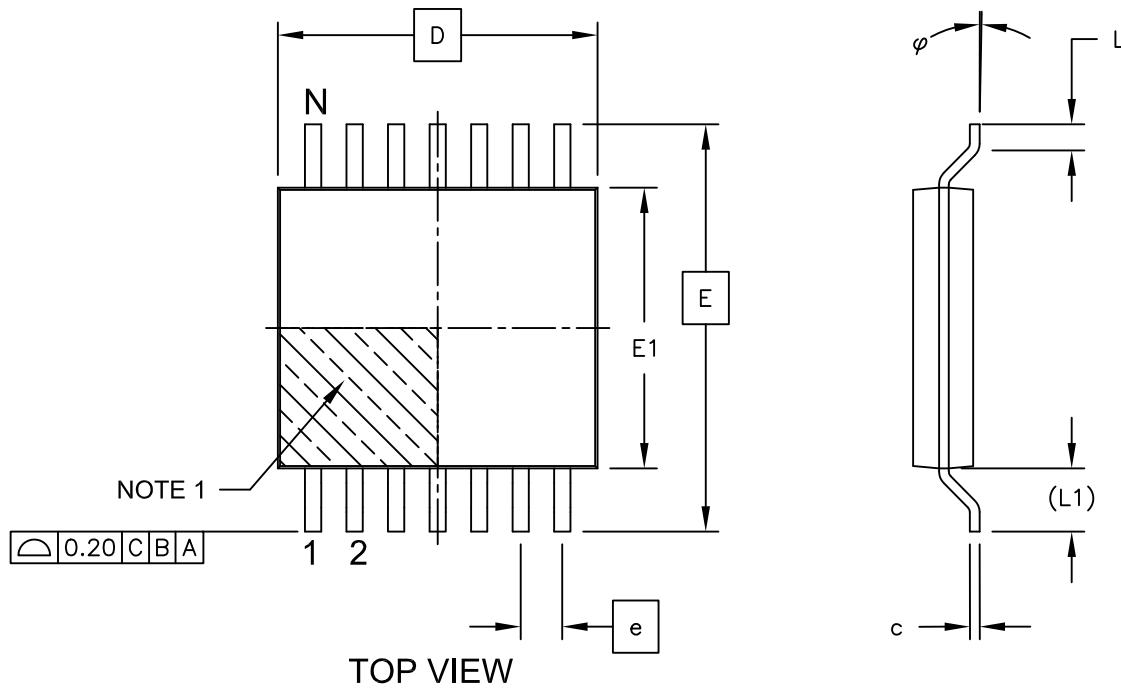
1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2065A

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>

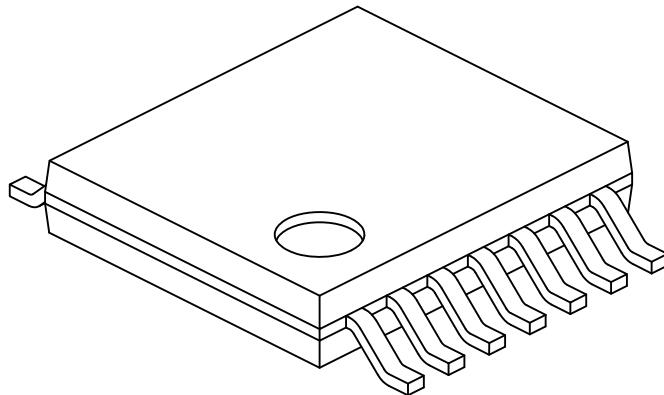


Microchip Technology Drawing C04-087C Sheet 1 of 2

MCP6021/1R/2/3/4

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



Units		MILLIMETERS		
Dimension Limits		MIN	NOM	MAX
Number of Pins		N		14
Pitch		e		0.65 BSC
Overall Height		A		1.20
Molded Package Thickness		A2		0.80 1.00 1.05
Standoff		A1		0.05 - 0.15
Overall Width		E		6.40 BSC
Molded Package Width		E1		4.30 4.40 4.50
Molded Package Length		D		4.90 5.00 5.10
Foot Length		L		0.45 0.60 0.75
Footprint		(L1)		1.00 REF
Foot Angle		φ		0° - 8°
Lead Thickness		c		0.09 - 0.20
Lead Width		b		0.19 - 0.30

Notes:

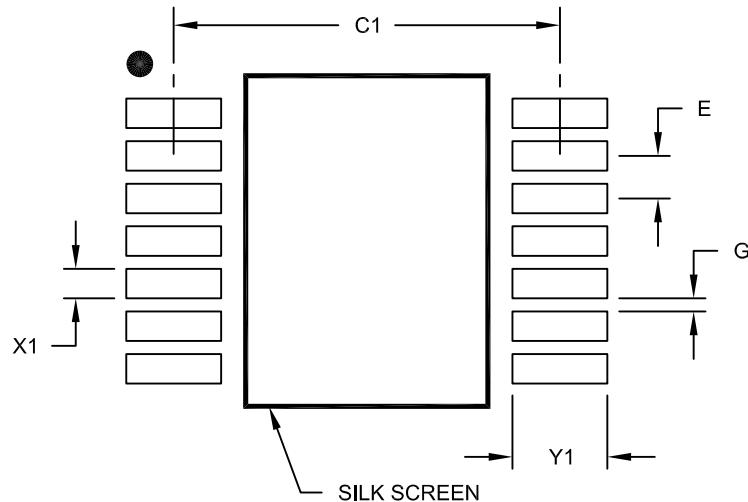
1. Pin 1 visual index feature may vary, but must be located within the hatched area.
2. Dimensions D and E1 do not include mold flash or protrusions. Mold flash or protrusions shall not exceed 0.15mm per side.
3. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

REF: Reference Dimension, usually without tolerance, for information purposes only.

14-Lead Plastic Thin Shrink Small Outline (ST) - 4.4 mm Body [TSSOP]

Note: For the most current package drawings, please see the Microchip Packaging Specification located at <http://www.microchip.com/packaging>



RECOMMENDED LAND PATTERN

Dimension Limits	Units	MILLIMETERS		
		MIN	NOM	MAX
Contact Pitch	E	0.65	BSC	
Contact Pad Spacing	C1		5.90	
Contact Pad Width (X14)	X1			0.45
Contact Pad Length (X14)	Y1			1.45
Distance Between Pads	G	0.20		

Notes:

1. Dimensioning and tolerancing per ASME Y14.5M

BSC: Basic Dimension. Theoretically exact value shown without tolerances.

Microchip Technology Drawing No. C04-2087A

MCP6021/1R/2/3/4

NOTES:

APPENDIX A: REVISION HISTORY

Revision E (January 2017)

The following is the list of modifications:

1. Updated the [AC Electrical Characteristics](#) table.
2. Added [Section 4.1.2, Input Voltage Limits](#) and [Section 4.1.3, Input Current Limits](#).
3. Added package information for 8-pin TSSOP.
4. Various typographical edits.

Revision D (February 2009)

The following is the list of modifications:

1. Changed all references to 6.0V back to 5.5V throughout document.
2. Design Aids: Name change for Mindi Simulation Tool.
3. [Section 1.0, Electrical Characteristics](#), [Section “AC Electrical Characteristics”](#): Corrected “Maximum Output Voltage Swing” condition from 0.9V Input Overdrive to 0.5V Input Overdrive.
4. [Section 1.0, Electrical Characteristics](#), [Section “AC Electrical Characteristics”](#): Changed Phase Margin condition from $G = +1$ to $G = +1$ V/V.
5. [Section 1.0, Electrical Characteristics](#), [Section “AC Electrical Characteristics”](#): Changed Settling Time, 0.2% condition from $G = +1$ to $G = +1$ V/V.
6. [Section 1.0, Electrical Characteristics](#): Added [Section 1.1, Test Circuits](#)
7. [Section 5.0, Design Aids](#): Name change for Mindi Simulation Tool. Added new boards to [Section 5.5, Analog Demonstration and Evaluation Boards](#) and new application notes to [Section 5.6, Application Notes](#).
8. Updates [Appendix A: “Revision History”](#)

Revision C (December 2005)

The following is the list of modifications:

1. Added SOT-23-5 package option for single op amps MCP6021 and MCP6021R (E-temp only).
2. Added MSOP-8 package option for E-temp single op amp (MCP6021).
3. Corrected package drawing on front page for dual op amp (MCP6022).
4. Clarified spec conditions (I_{SC} , PM and THD+N) in [Section 2.0, Typical Performance Curves](#).
5. Added [Section 3.0, Pin Descriptions](#).
6. Updated [Section 4.0, Applications Information](#) for THD+N, unused op amps, and gain peaking discussions.
7. Corrected and updated package marking information in [Section 6.0, Packaging Information](#).
8. Added [Appendix A: “Revision History”](#).

Revision B (November 2003)

- Second Release of this Document

Revision A (November 2001)

- Original Release of this Document

MCP6021/1R/2/3/4

NOTES:

PRODUCT IDENTIFICATION SYSTEM

To order or obtain information, e.g., on pricing or delivery, refer to the factory or the listed sales office.

<u>PART NO.</u>	<u>I</u> ⁽¹⁾	<u>X</u>	<u>XX</u>	Examples:
Device	Tape and Reel Option	Temperature Range	Package	
Device:	MCP6021 Single Op Amp MCP6021T Single Op Amp (Tape and Reel for SOT-23, SOIC, TSSOP, MSOP) MCP6021R Single Op Amp MCP6021RT Single Op Amp (Tape and Reel for SOT-23) MCP6022 Dual Op Amp MCP6022T Dual Op Amp (Tape and Reel for SOIC and TSSOP) MCP6023 Single Op Amp w/CS MCP6023T Single Op Amp w/CS (Tape and Reel for SOIC and TSSOP) MCP6024 Quad Op Amp MCP6024T Quad Op Amp (Tape and Reel for SOIC and TSSOP)			a) MCP6021T-E/OT: Tape and Reel, Extended temperature, 5LD SOT-23. b) MCP6021-E/P: Extended temperature, 8LD PDIP. c) MCP6021-E/SN: Extended temperature, 8LD SOIC.
Tape and Reel Option:	Blank = Standard packaging (tube or tray) T = Tape and Reel ⁽¹⁾			a) MCP6021RT-E/OT: Tape and Reel, Extended temperature, 5LD SOT-23.
Temperature Range:	I = -40°C to +85°C (Industrial) E = -40°C to +125°C (Extended)			a) MCP6022-I/P: Industrial temperature, 8LD PDIP. b) MCP6022-E/P: Extended temperature, 8LD PDIP. c) MCP6022T-E/ST: Tape and Reel, Extended temperature, 8LD TSSOP.
Package:	OT = Plastic Small Outline Transistor (SOT-23), 5-Lead (MCP6021, E-Temp; MCP6021R, E-Temp) MS = Plastic MSOP, 8-Lead (MCP6021, E-Temp) P = Plastic DIP (300 mil Body), 8-Lead, 14-Lead SN = Plastic SOIC (150 mil Body), 8-Lead SL = Plastic SOIC (150 mil Body), 14-Lead ST = Plastic TSSOP, 8-Lead (MCP6021, I-Temp; MCP6022, I-Temp, E-Temp; MCP6023, I-Temp, E-Temp) ST = Plastic TSSOP, 14-Lead			a) MCP6023-I/P: Industrial temperature, 8LD PDIP. b) MCP6023-E/P: Extended temperature, 8LD PDIP. c) MCP6023-E/SN: Extended temperature, 8LD SOIC.
				a) MCP6024-I/SL: Industrial temperature, 14LD SOIC. b) MCP6024-E/SL: Extended temperature, 14LD SOIC. c) MCP6024T-E/ST: Tape and Reel, Extended temperature, 14LD TSSOP.
				Note 1: Tape and Reel identifier only appears in the catalog part number description. This identifier is used for ordering purposes and is not printed on the device package. Check with your Microchip Sales Office for package availability with the Tape and Reel option.

MCP6021/1R/2/3/4

NOTES:

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